

Detectors for Current and Future Synchrotron Light Sources

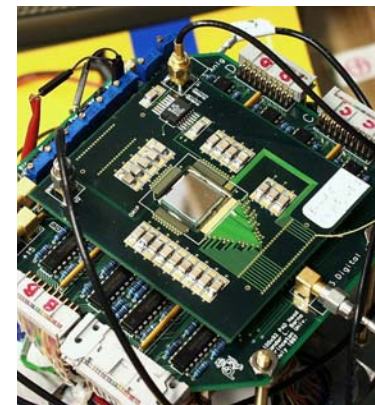
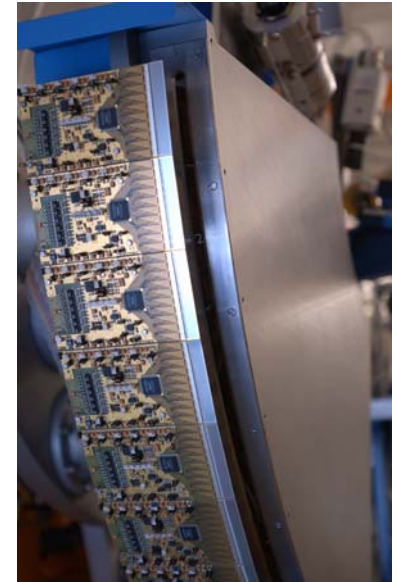
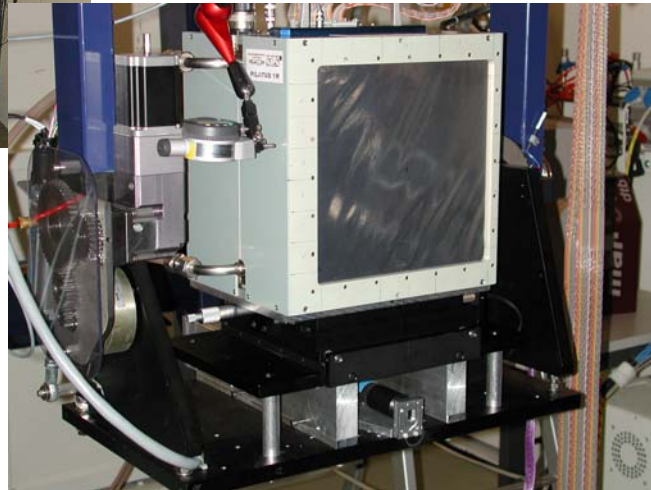
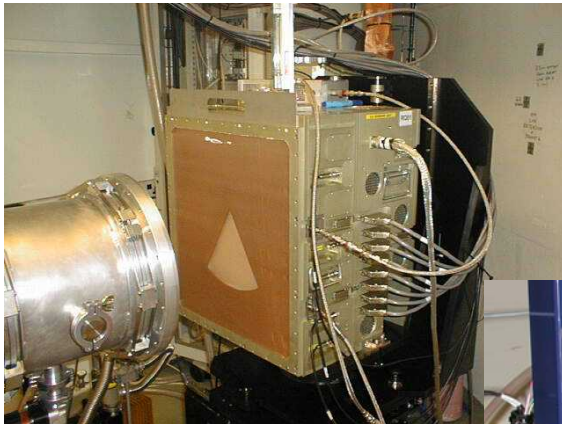
Christian Brönnimann

Group Leader SLS Detector Group

Paul Scherrer Institut

CH-5232 Villigen-PSI, Switzerland

IWORID 7, 4.-7.7.05, ESRF



Detectors for Current and Future Synchrotron Light Sources

1. Introduction
2. Existing Detector Systems
 - Rapid
 - Mythen
 - Pilatus
3. Future Detector Systems
 - Pilatus XFS
 - APAD
 - Analog Hybrid Pixels for FEL Apps
4. Conclusions

Synchrotrons Worldwide



New Projects in Europe:

- Soleil, Fr (2006)
- Diamond, UK (2006)
- Petra upgrade, Ge (2009)
- Alba, Esp, (2010)
- Tesla FEL (2010)

- High demand for detectors in Europe
 - Current and future science more limited by the detectors than the sources
- >optimized detector systems for SR

The Source - Detector Mismatch in the SR community

Detector development was systematically under-funded

Huge mismatch btw properties of the source and capabilities of the detectors:

Count rate limitations

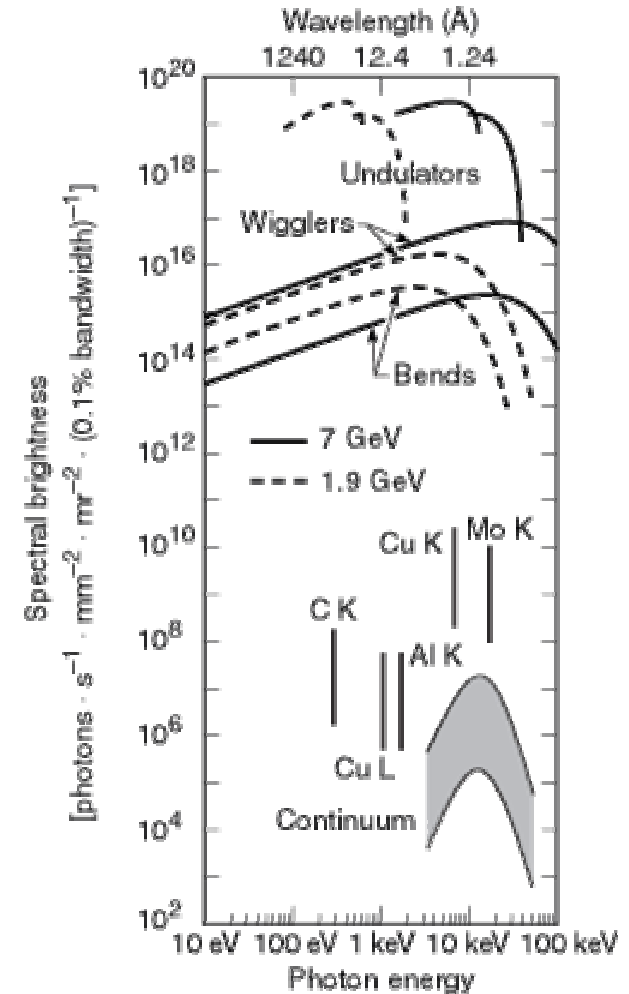
Long readout times

Solid angle coverage

Detection efficiency

SR experiments are very diverse

We must deal more efficiently with the radiation delivered by the synchrotrons



The Source - Detector Mismatch in the SR community

Examples:

Count rate limitations

Pilatus I: 10 kHz/pixel/s \rightarrow $2.5 \cdot 10^7$ /cm²/s

SLS X06SA PX I BL: Beam Intensity attenuated to 3%

Al-Filters in the beam to avoid saturation or damage of detector is a common situation

Long readout times

Mar165 CCD at BL X06SA: $t_{\text{exp}}=1\text{s}$, $t_d=3\text{s}$

$$\text{duty cycle} = \frac{t_{\text{exp}}}{t_{\text{exp}} + t_d} = 25\%$$

Radiation Hardness

3 years of operation: > 3 Mrad

Direct beam (SLS X04SA Wiggler Bl): 250krad/s/pixel

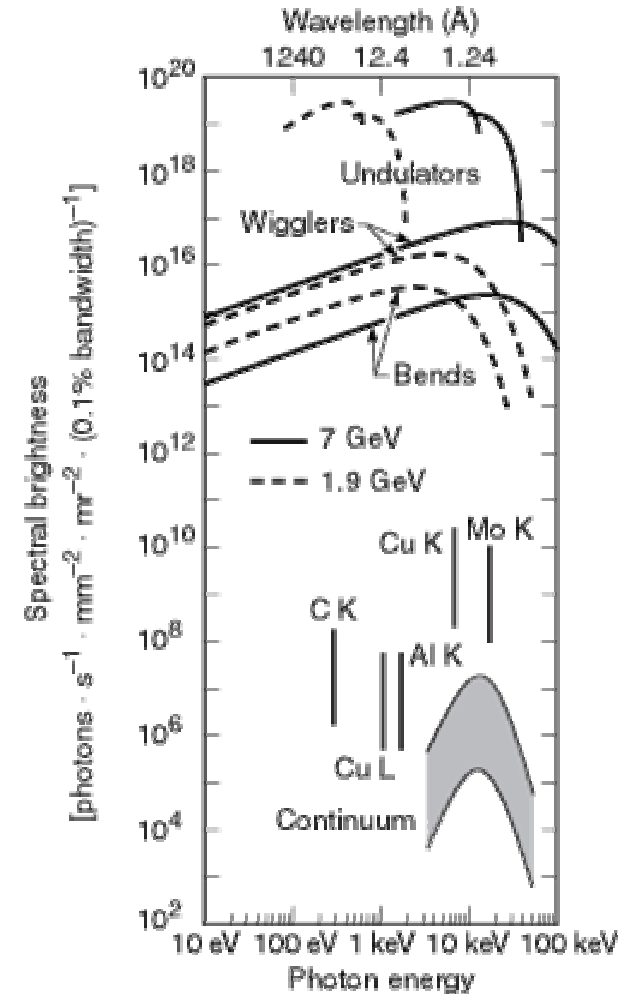
Solid angle coverage

Analyzer crystals for Powder diffraction

Point detectors on diffractometers

Detection efficiency

$E_{\text{ph}} > 20$ keV



Requirements for SR Detectors

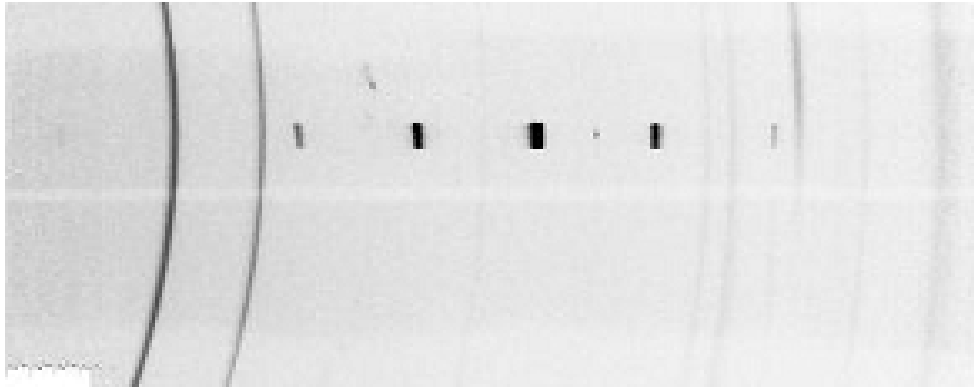
- High local and global count rate capability
- Short read-out time
- High spatial resolution
- High dynamic range
- High detection efficiency
- Large solid angle coverage
- Very good signal to noise ratio
- Precise calibration
- Radiation hardness
- (Software Integration ↔ User operation)

Single Photon Counting Detectors (?)

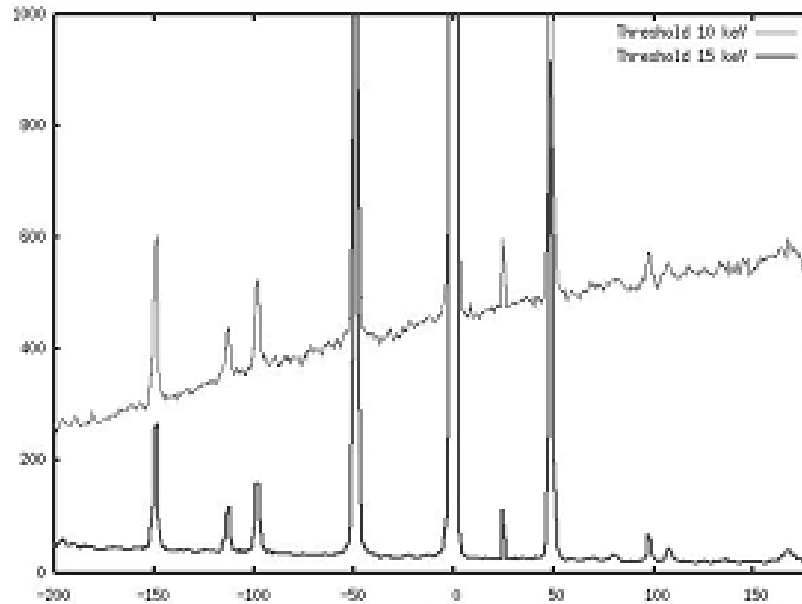
Single Photon Counting vs Integrating Detectors for SR

Property	Single Photon Counting	Integrating
Detection	Charge of Photon is amplified, counting above predefined threshold	Charge is integrated in Pixel
Count-Rate	Limited, dead time corrections for high rates, 1 MHz/pixel	Unlimited
Read-out	Digital highly parallel data transmission, Noisefree, 1 ms	Analog data transmission, ADC conversion, noise of few X-rays added, >100ms
Spatial resolution	> 55 x 55 μm^2 , PSF 1 pixel,	> 10 x 10 μm^2 , PSF type depending
Dynamic Range	10^6	10^4
Detection efficiency	74% at 12 keV, low above 20keV	Depending on scintillator
Solid angle coverage	Modular detectors	CCD > 30 x 30 cm^2
Signal to noise ratio	Fluorescent background suppression	Limited by dark current and readout noise
Calibration	Energy calibration with X-rays Rate calibrations	Established corrections procedures
Radiation Hardness	Several Mrad required	Several Mrad required

Single Photon Counting: Fluorescent background suppression



Diffraction pattern from GaAs/AlAs sample at the 18 keV X-ray beam

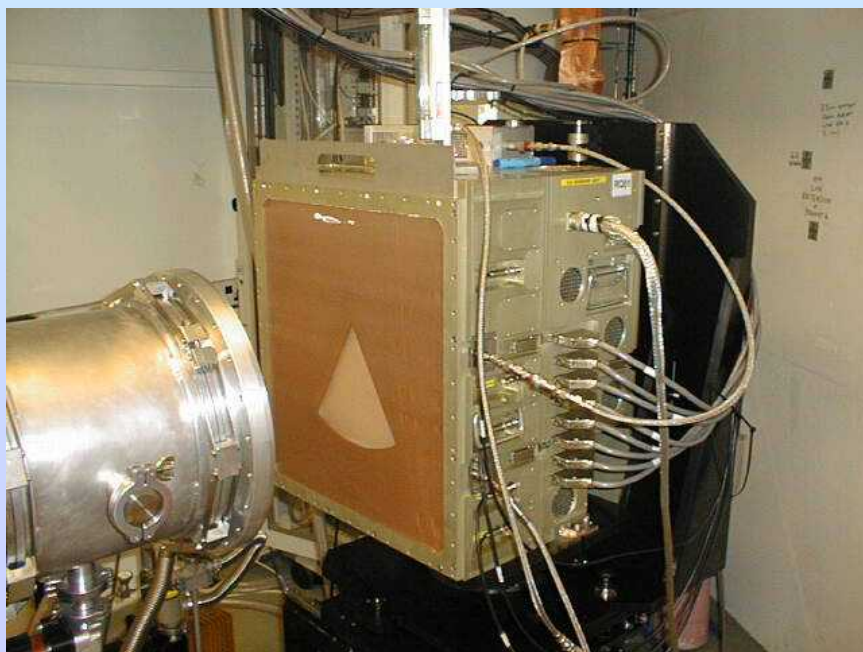
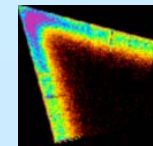


Results for 2 different threshold settings

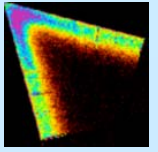
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The Rapid2 SAXS/WAXS micro-gap detectors

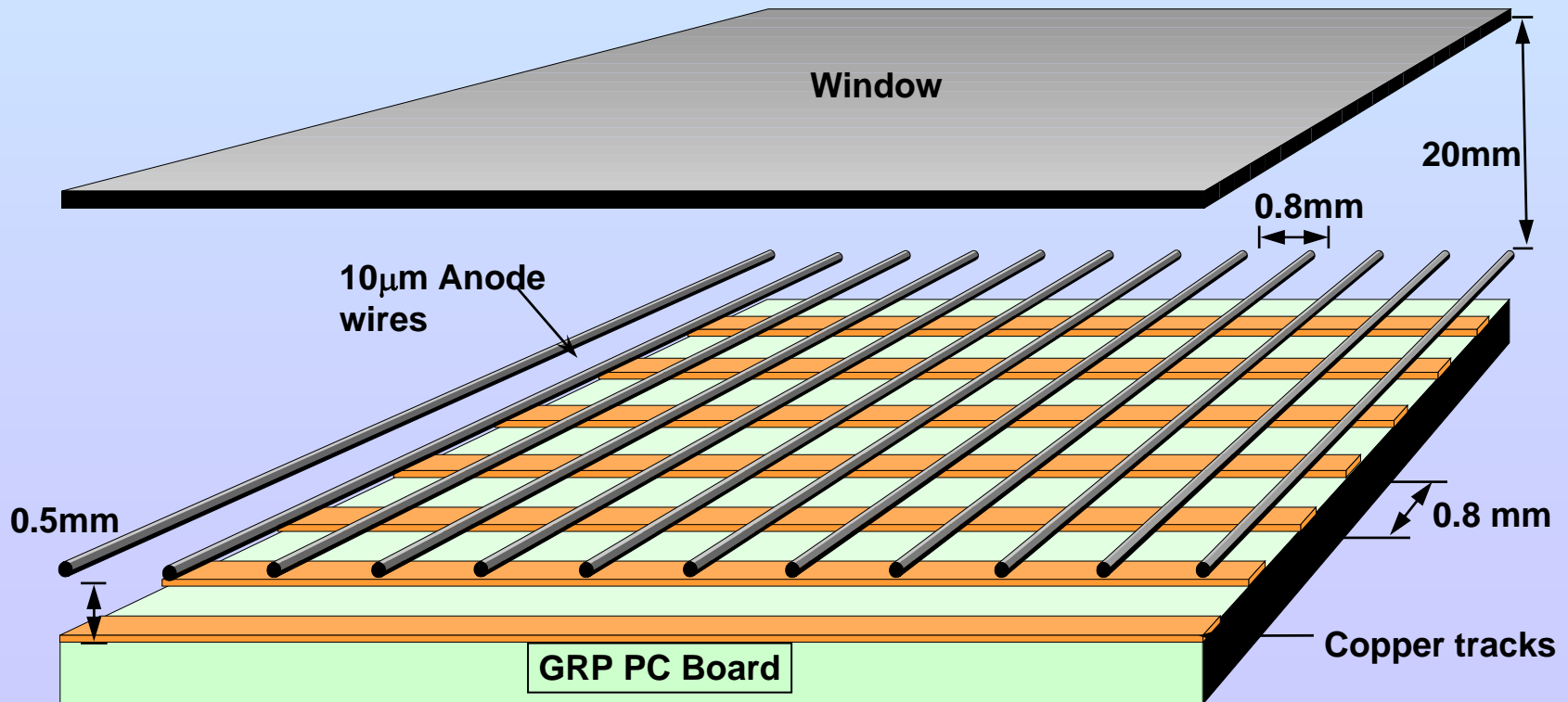


Wire MicroGap Detector

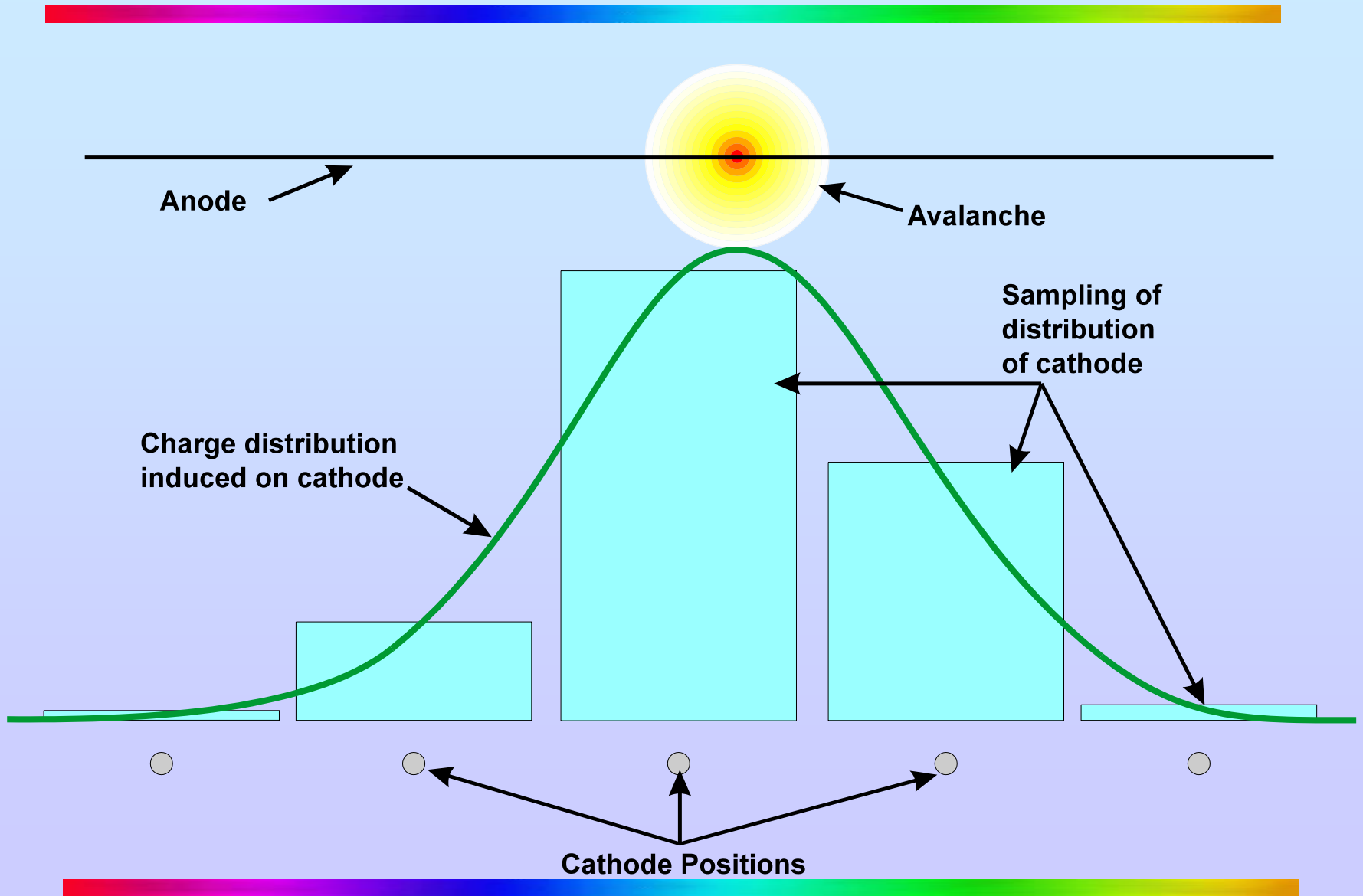
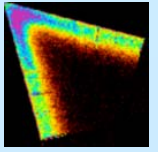


- Small Anode to Cathode gap (0.5 mm) gives good local count rate.
- Intrinsically 2D
- Difficult to maintain anode/cathode gap.

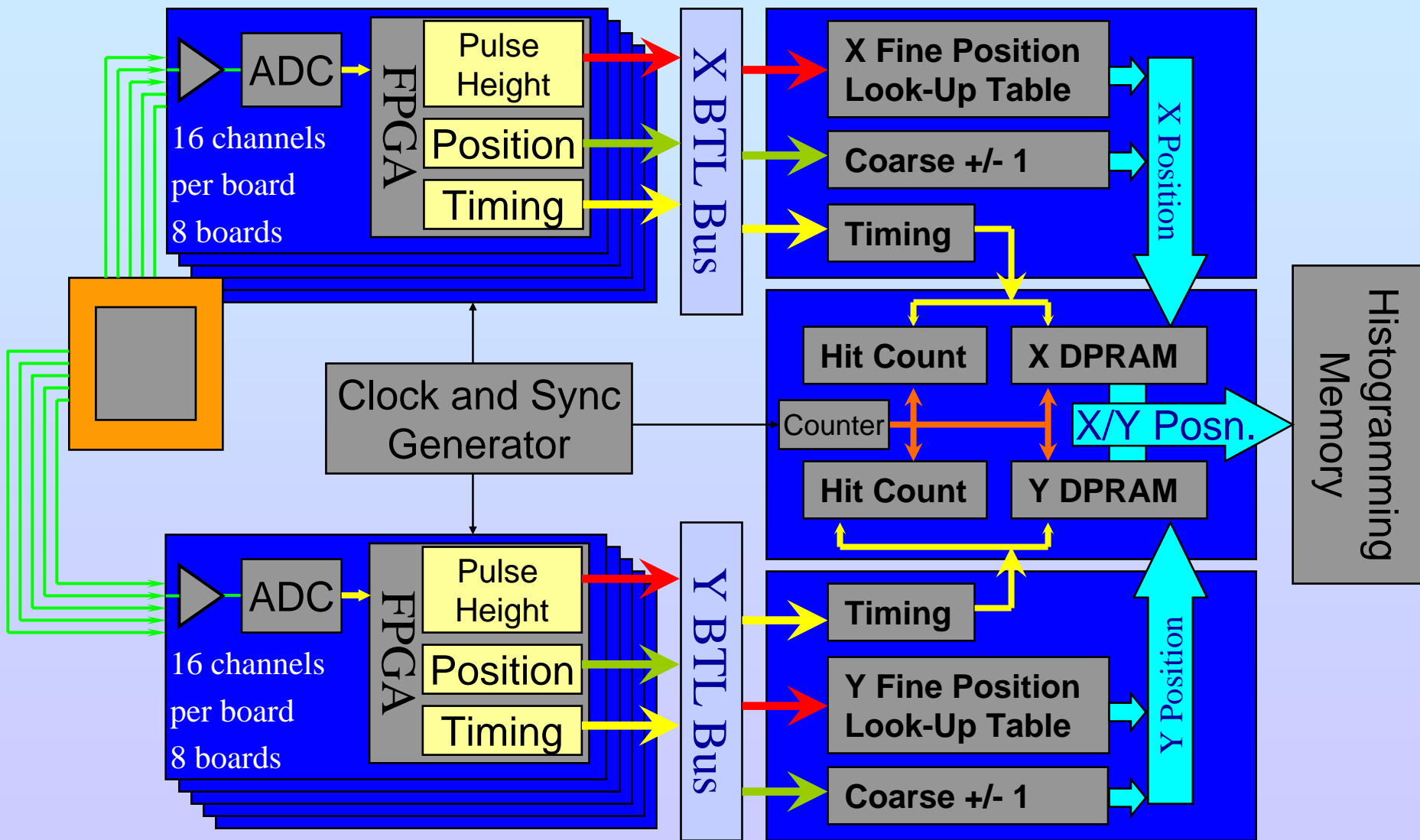
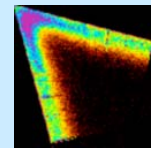
Careful control of wire tension and PCB flatness



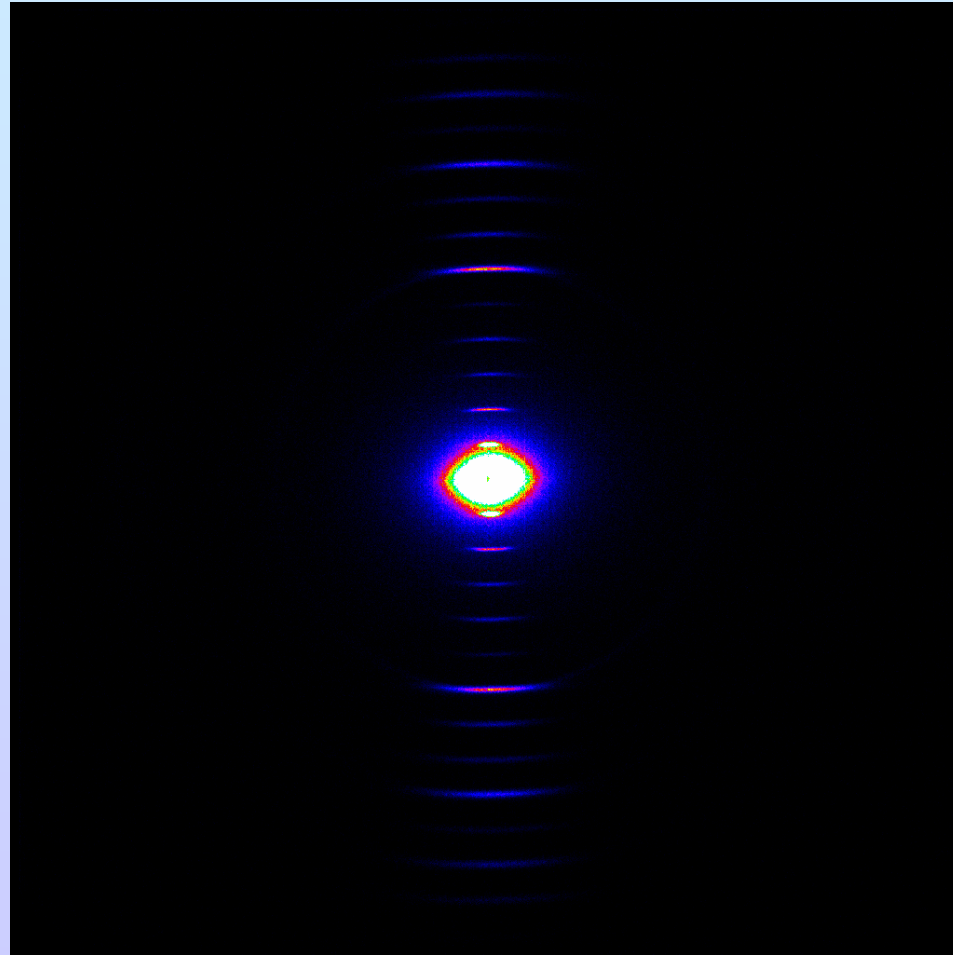
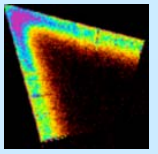
Charge Distribution



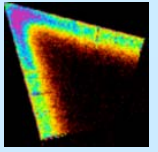
RAPID 2 as 2D Data Acquisition System



Collagen Collected at Spring-8 with 2D RAPID 2

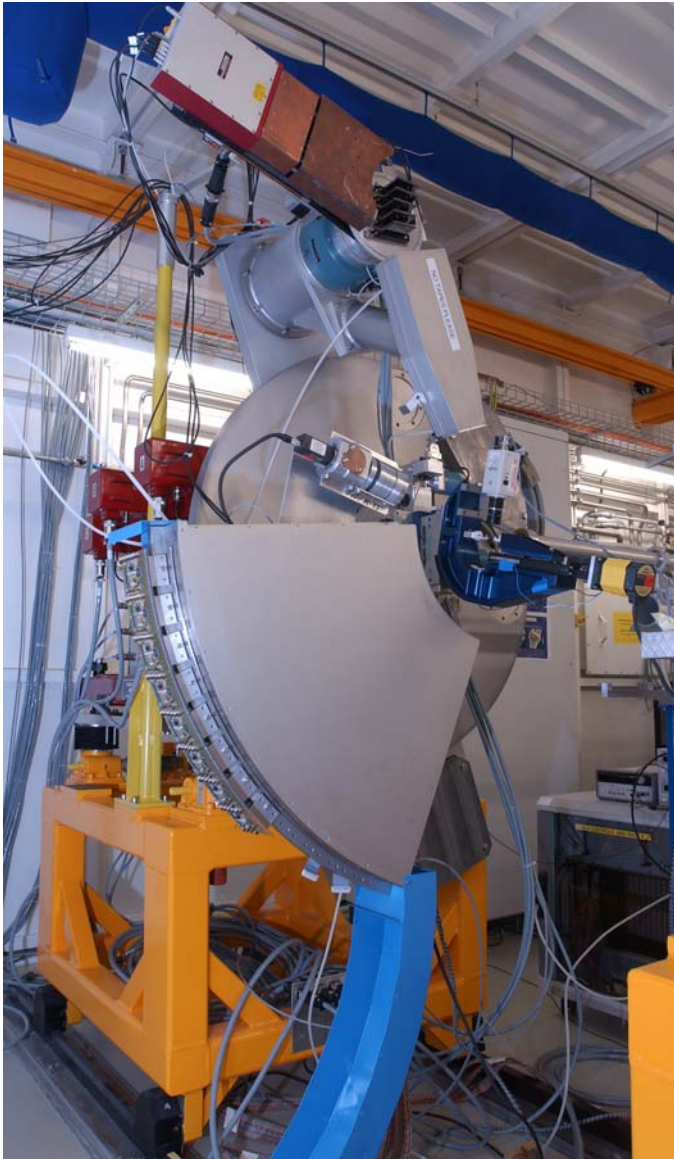


Rapid detector system



- **High parallel readout system for Multi Wire proportional counters.**
- **Can readout 1D and 2D detectors**
- **Uses ADC per channel to provide interpolation.**
 - **Gives spatial resolution of typically 512 to 4096 pixels from 128 channels**
- **Count rate performance**
 - **1D – Up to 40×10^6 Events/s**
 - **2D – Up to 15×10^6 Events/s**
 - **Maximum Frame rate > 1KHz**

Powder Diffraction with Mythen Detector (SLS BL X04SA)

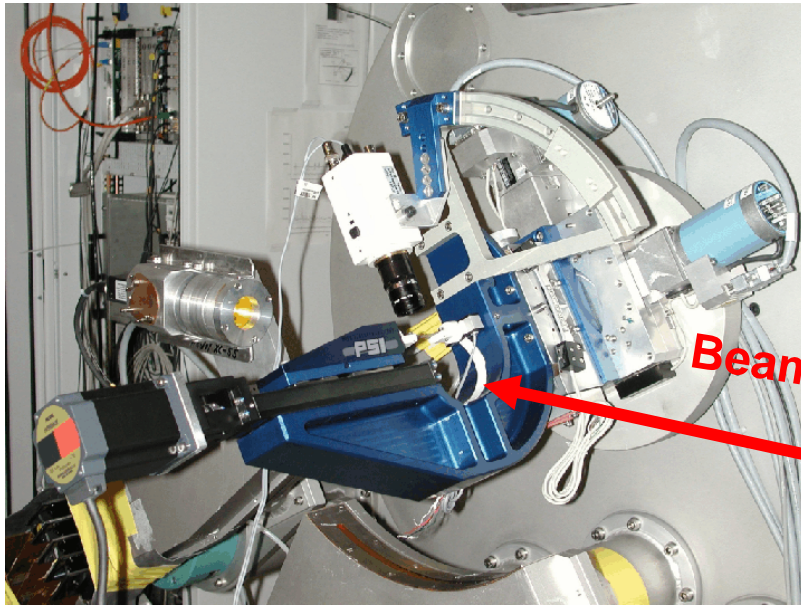


Array of Microstrip Detectors
Angular coverage: 60°
No of channels: 15000
Angular resolution : 0.004°
Read-out time: $250 \mu\text{s}$

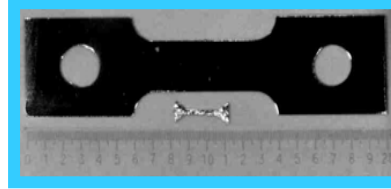


time resolved powder
diffraction

In-situ peak profile analysis of nanocrystalline Ni at SLS



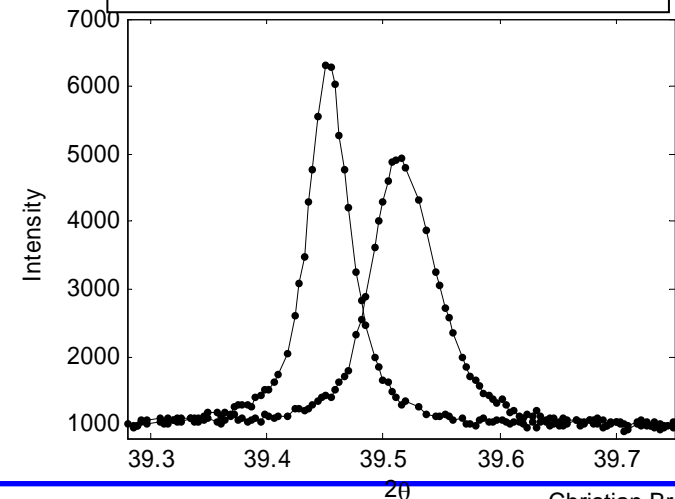
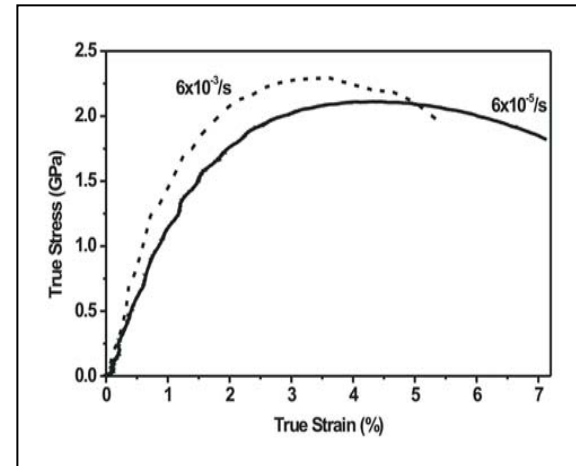
Microstrip-detector



In-Situ X-ray diffraction measurements
of deformation mechanisms

Full powder pattern recorded every 5 seconds

Science, 304 (2004)
Nat. Mat., June (2004)



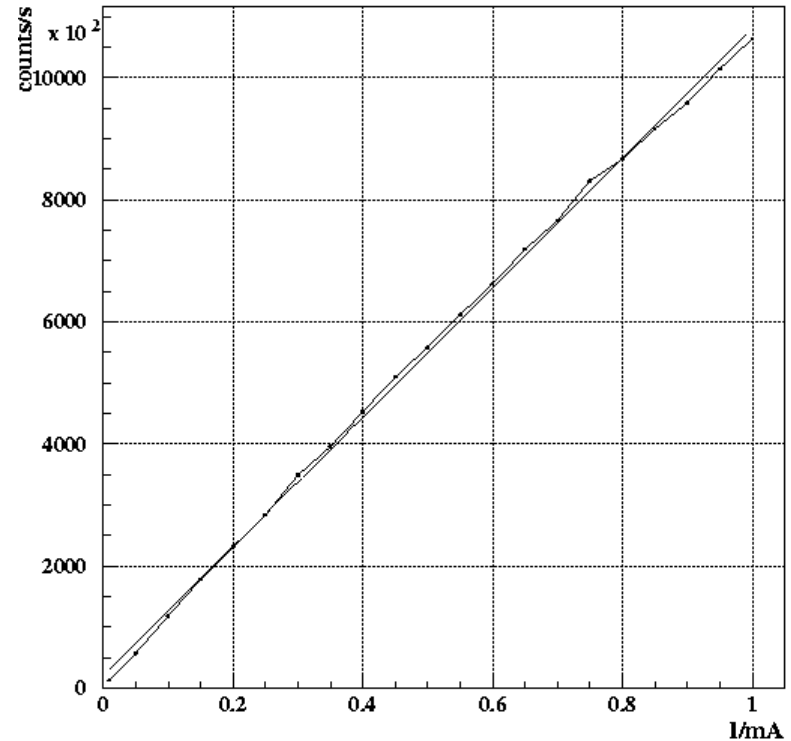
Mythen V2 (B. Schmitt)

New 0.25 μm readout chip available

Features:

- 128 channels
- Low noise <240 e- ENC
- 6 trim bits High count rate: linear to $>1\text{MHz}$ (measured with X-rays)
- 24 bit counter with variable length readout, readout time from $32 \mu\text{s}$ (4bit) to $64 \mu\text{s}$ (24bit) for entire chip/detector
- Frame rates of 10kHz are planned

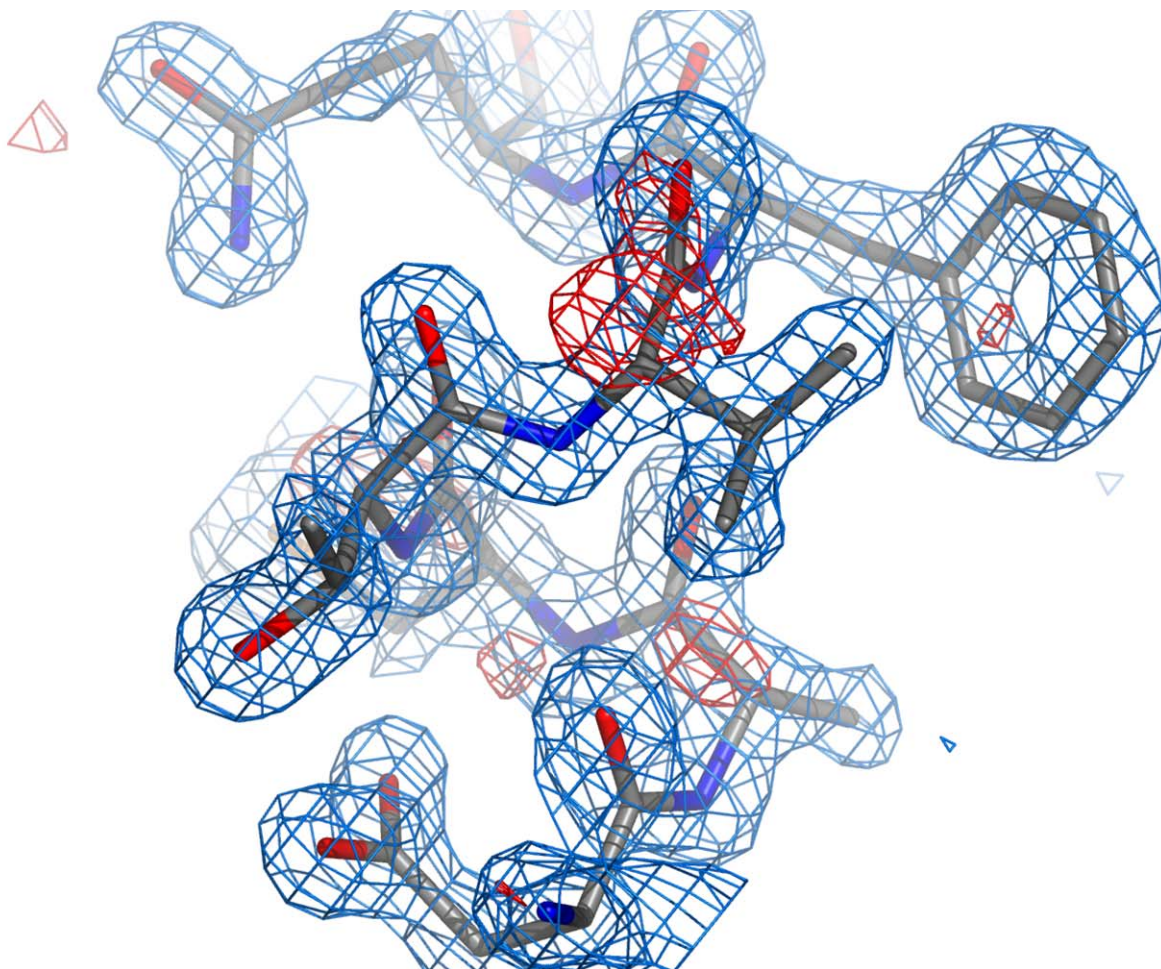
Current detector will be replaced by V2 in 2005



The PILATUS 1M Detector for Protein Crystallography

- Largest pixel detector array for SR
- 6 banks a 3 modules, 1120 x 967 pixels
- Area: 21 x 24 cm²
- 288 chips->~300x10⁶ transistors
- Readout time: 6.7ms
- 2 frames/ s
- Active area: 85%
- Moderate count rates (<10kHz/pixel)
- PX Data processing difficult due to counting errors of PILATUS I chip





Thaumatin electron density map

Merging of 3 datasets at 3 positions

Processing with XDS

Refinement with SHELXL

Completeness: 90.3%

R_{sym} 8.4%

Resolution: 1.4 Å

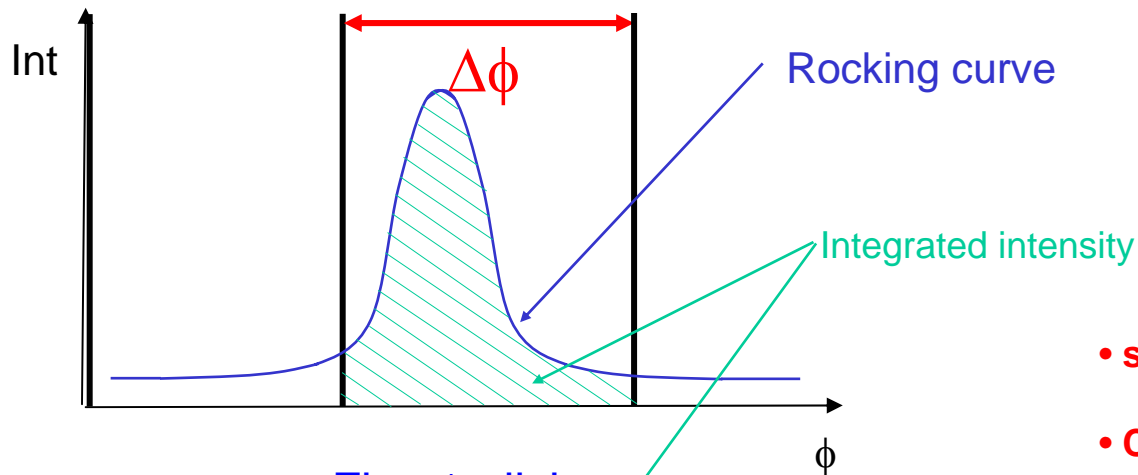
Refinement:
R-Factor 28%

blue contours: $2 \cdot F_o - F_c$ (2sigma)
red contours: $F_o - F_c$ (2sigma)

Ch. Broennimann et al, "The PILATUS 1M Detector", submitted to J. Synchrotron Rad. (2005)
G. Huelsen et al., "Distortion Calibration of the PILATUS 1M Detector", accepted by NIM 2005

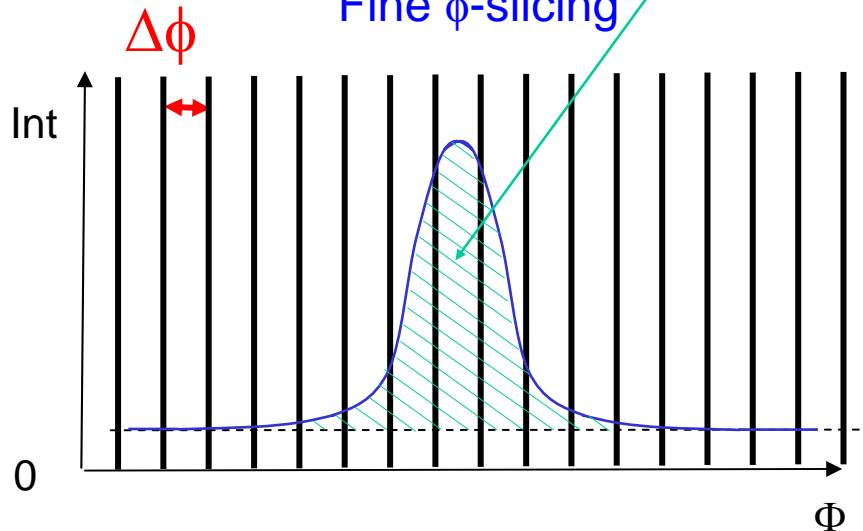
Fine ϕ -slicing with the PILATUS Detector

Conventional Integration



- short readout-time
- Continuous rotation -> no shutter
- no read-out noise

Fine ϕ -slicing

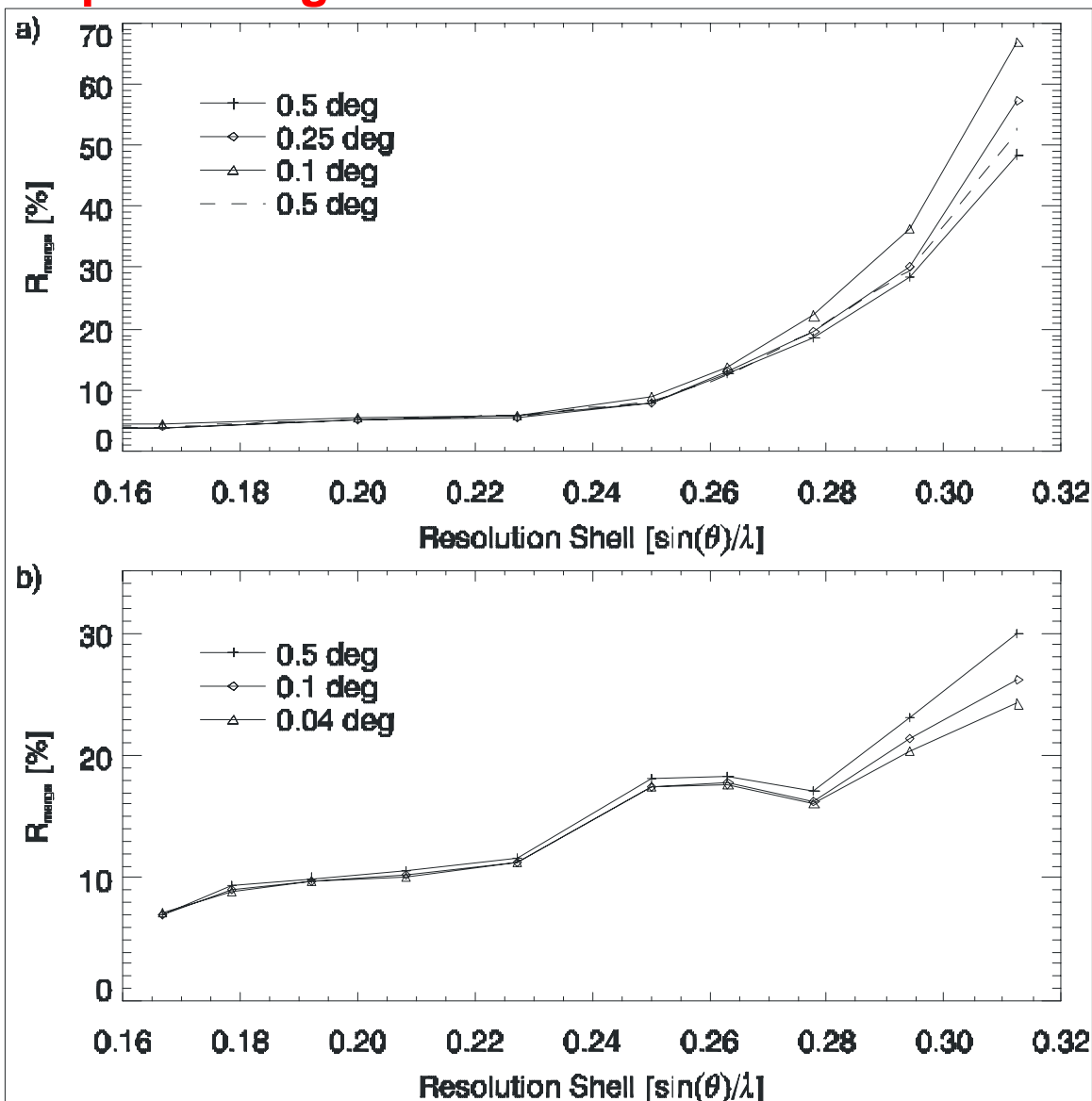


Angular speed ω ,
Exposure time t
 $\Delta\phi = t \cdot \omega$

Results of Fine-phi slicing data-sets

CCD Data:

Finer slicing -> more
readout noise, -> higher
R-Factors



PILATUS 1M Data:

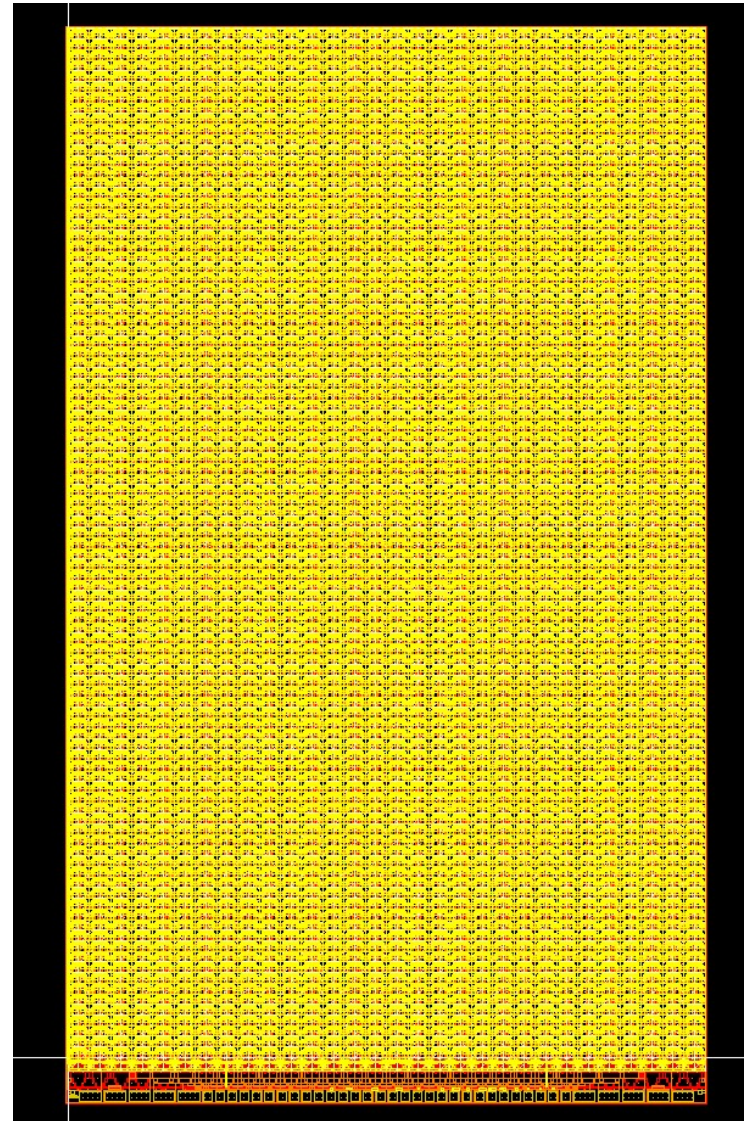
Finer slicing -> higher ϕ -
resolution -> somewhat
lower R-Factors

New version of XDS from W.
Kabsch to process the 9000
frames a 0.02°/frame

G. Huelsen et al., "Protein Crystallography with a Novel Large Area Pixel Detector", in preparation

PILATUS II Chip

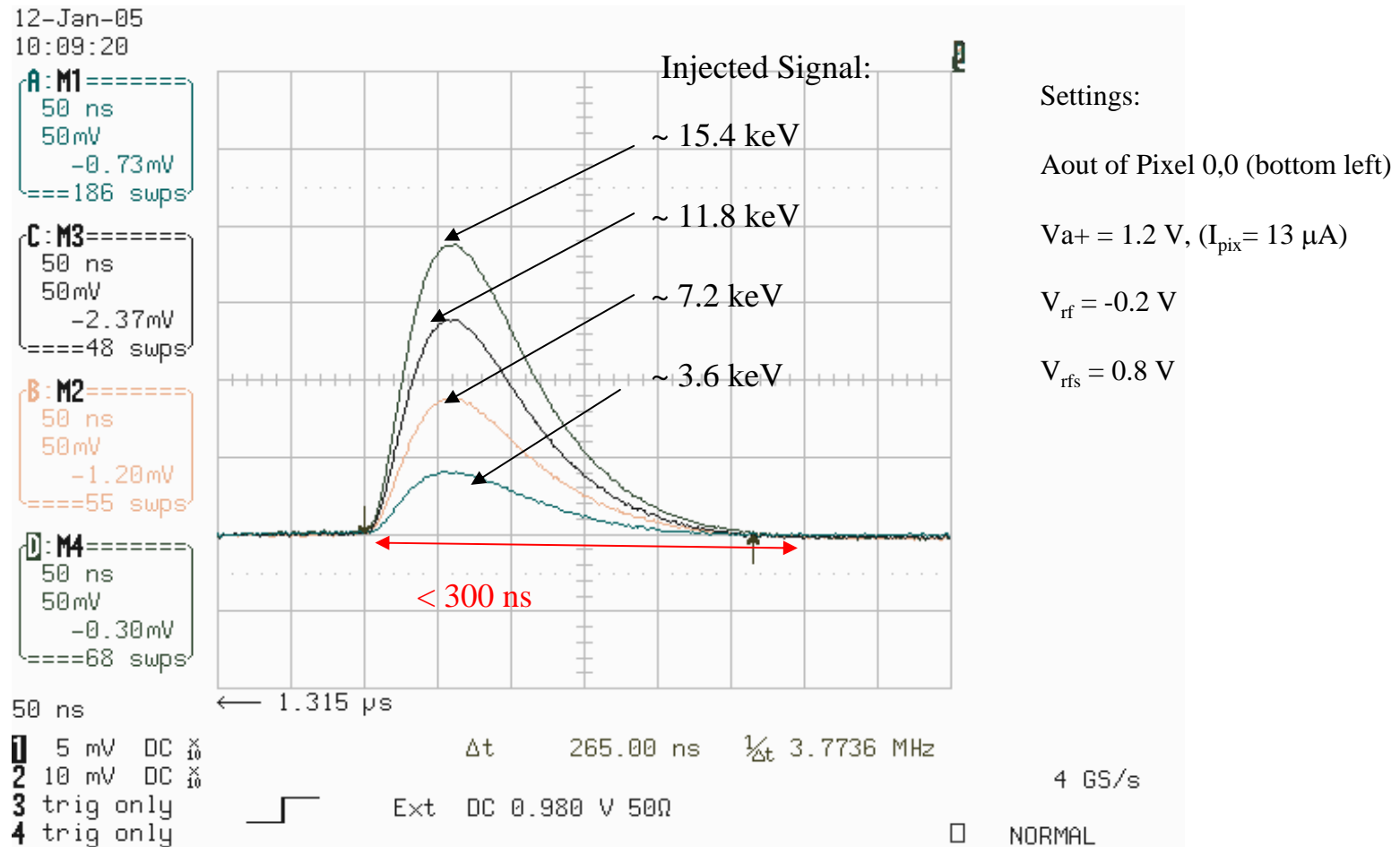
- UMC_25_MMC process; Radiation hard design
 - 60 x 97 pixels = 5820 pixels
 - Pixel size 172 x 172 μm^2
 - 17.540 x 10.450 mm^2
 - Count rate: 1MHz/pixel
 - 20 bit counter
 - Counting timer circuit
 - 6 bit DAC for threshold adjustment
 - XY-adressable
 - Analog output
 - 75 MHz LVDS readout ($T_{ro} = 2 \text{ ms}$)
 - Submitted 29.09.04
 - Received 1.12.04
- 4*10⁶ Transistors



Philipp Kraft, Characterization of the Readout Chip for the PILATUS 6M Detector, ETHZ-IPP Internal Report 2005-03 (March 2003)

Available on-line soon

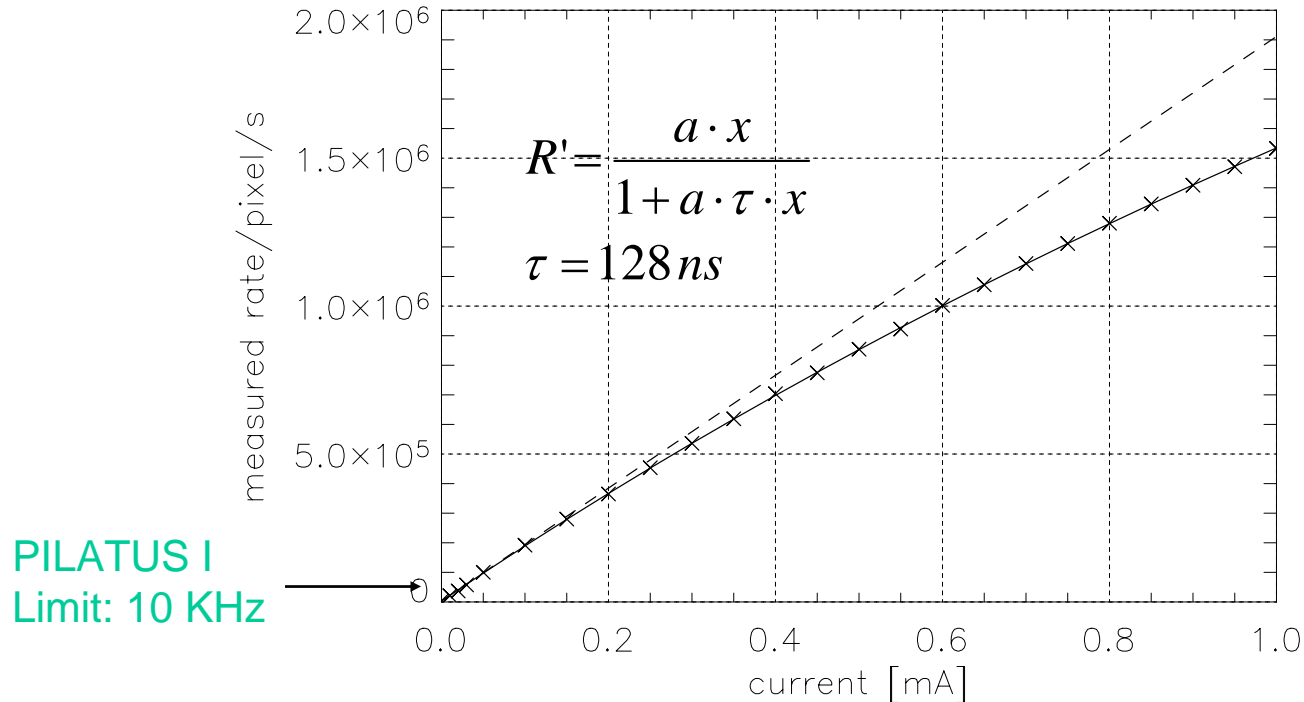
PILATUS II: CS Amplifier



10^6 photons/s/pixel with poisson distributed time-intervals should be possible

PILATUS II Rate Tests

8keV X-rays, avg rate of 20 pixels



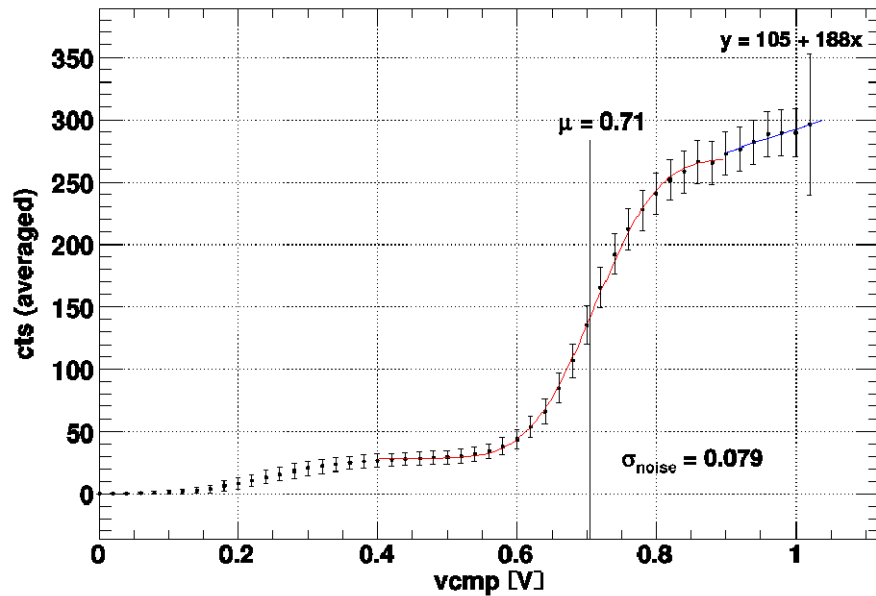
Count Rate capability:

- local $1.5 \cdot 10^6$ X-rays/s/pixel
- global $5 \cdot 10^7$ X-rays/s/mm²

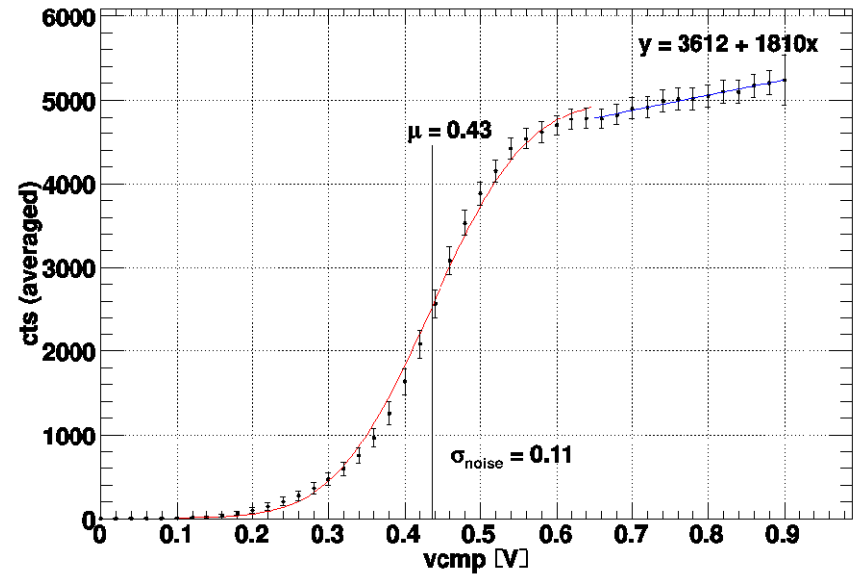
PILATUS II V_{cmp} calibration

V_{cmp} scans from flat-field illuminations, after trimming, averaged over all pixels

6 keV



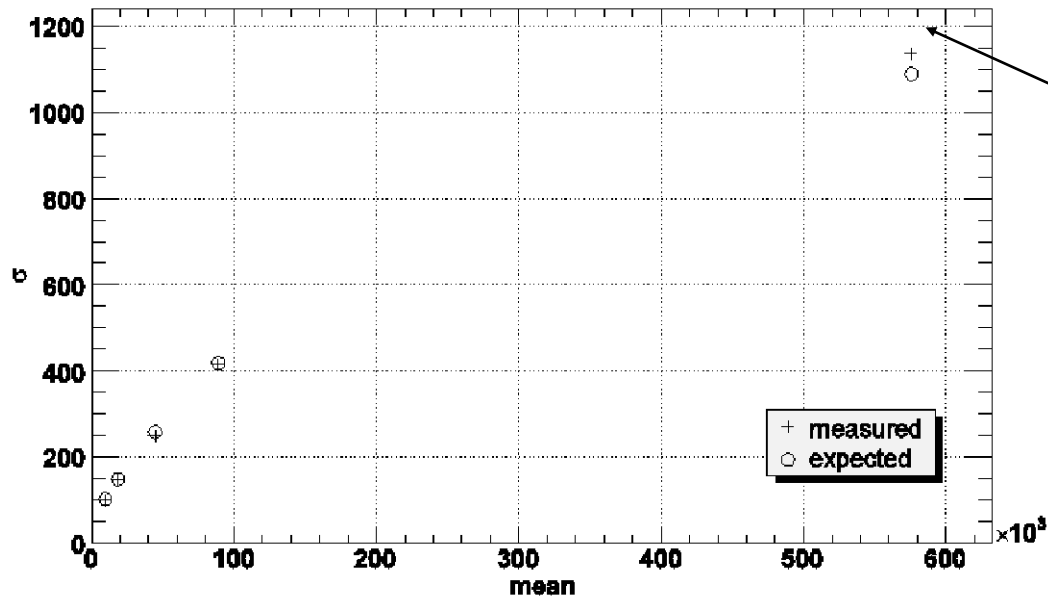
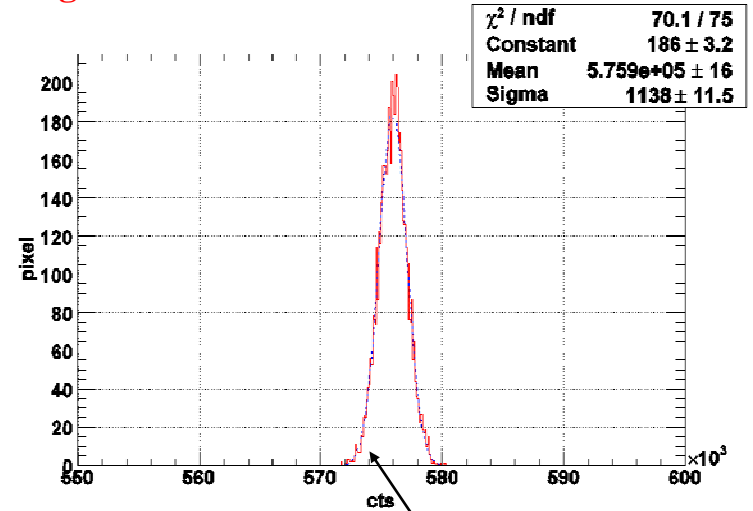
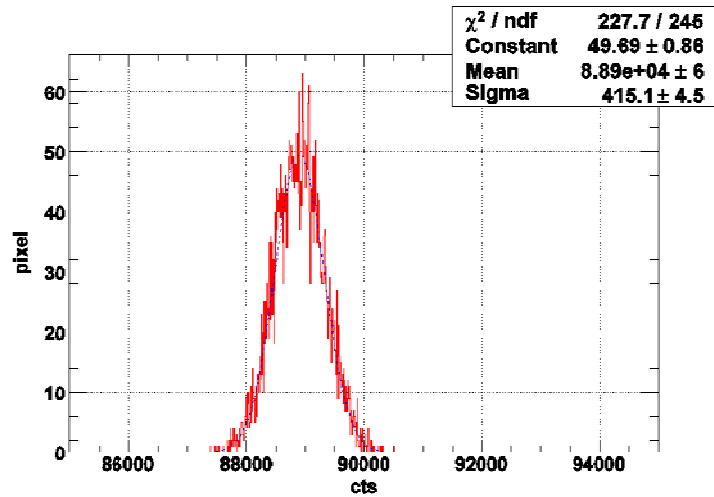
8 keV



$$\sigma = 158 e^- (= 570 eV)$$

Pilatus II Counting Statistics

Flat-field Images after trimming at 12 keV



Statistical variation after flatfield correction:
 $\sigma(I)/I=0.2\%$

Radiation Hardness (preliminary)

Counting detector delivers

deposited dose directly:

$$D = \frac{N_x \cdot E_x}{m_p}, \text{ with}$$

$$N_x = 10^6 / \text{pix} / \text{s}$$

$$E_x = 13.5 \text{ keV}$$

$$m_p = 2 \cdot 10^{-5} \text{ g}$$

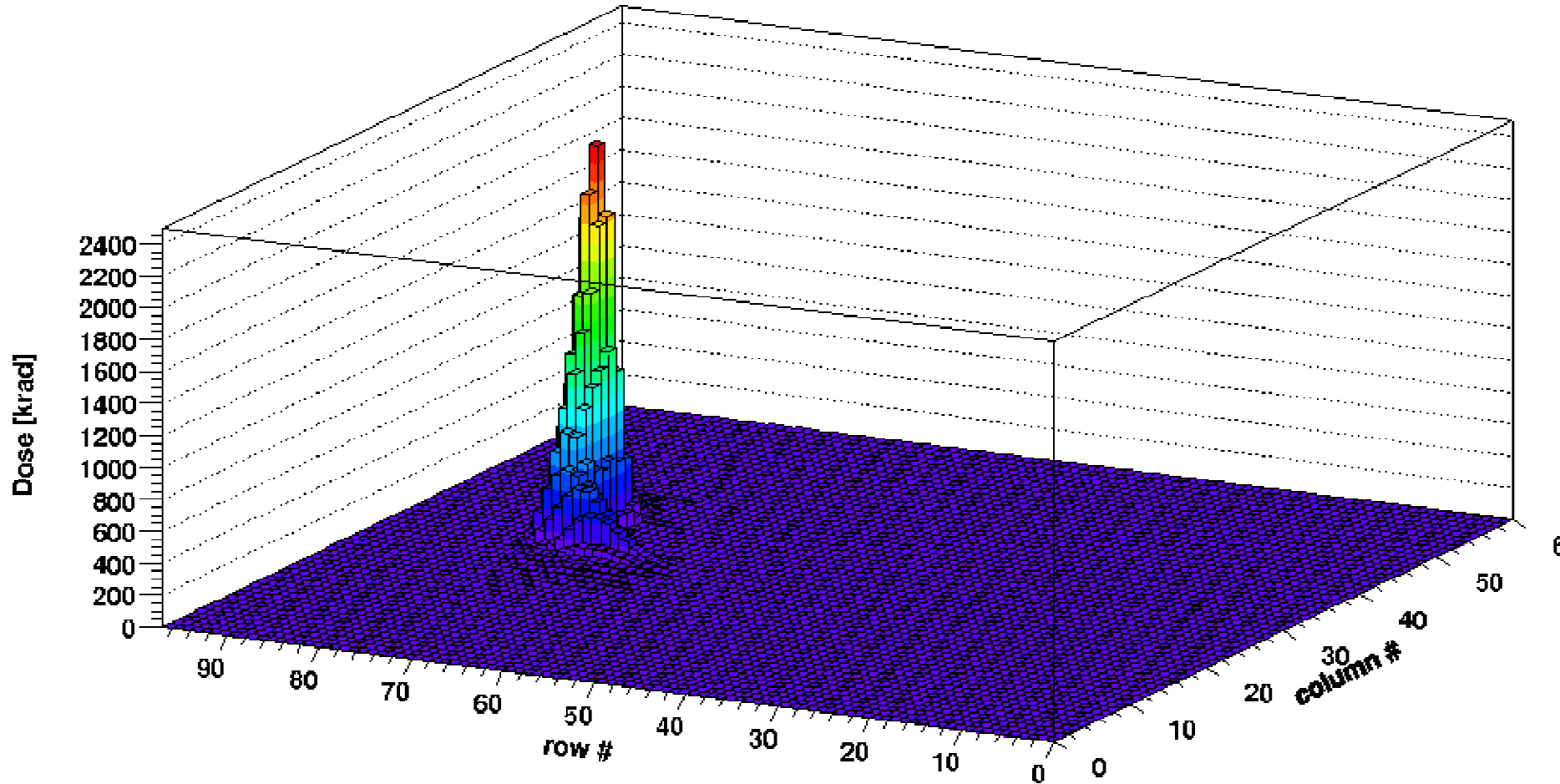
$$1 \text{ rad} = 6 \cdot 10^{10} \text{ keV} / \text{g}$$

$$\Rightarrow D = 10 \text{ rad} / \text{s}$$

- Put Pilatus II chip in direct beam
- Adjusted beam intensity to obtain $\sim 10^6$ X-rays/pixel
- Increased beam intensity by 100
-> $\sim 10^8$ X-rays/pixel
- -> central pixels saturated
- Exposed for 3600s
- Peak doses $\sim 2 - 3$ Mrad (20- 30 Gy)
- Flat field illumination before and after irradiation
-> count rate variation $< 1\%$

Pilatus II Chip + Sensor are radiation hard

Distribution of Dose on Chip



PILATUS II: Single Module



Module:
1 Hamamatsu Sensor
16 Pilatus II Chips
Bump bonded with new CMS Bump -
bonding machine: ~ 80 minutes/module

Hybrid from Dyconex

Mechanical support

Module Control Board

Module Parameters:

487 x 195 = 94'965 pixel

$T_{ro} = 2 \text{ ms}$

Maximum Frame Rate with Gigastar PCI Card: 150 Hz

^{55}Fe Irradiation (6keV):

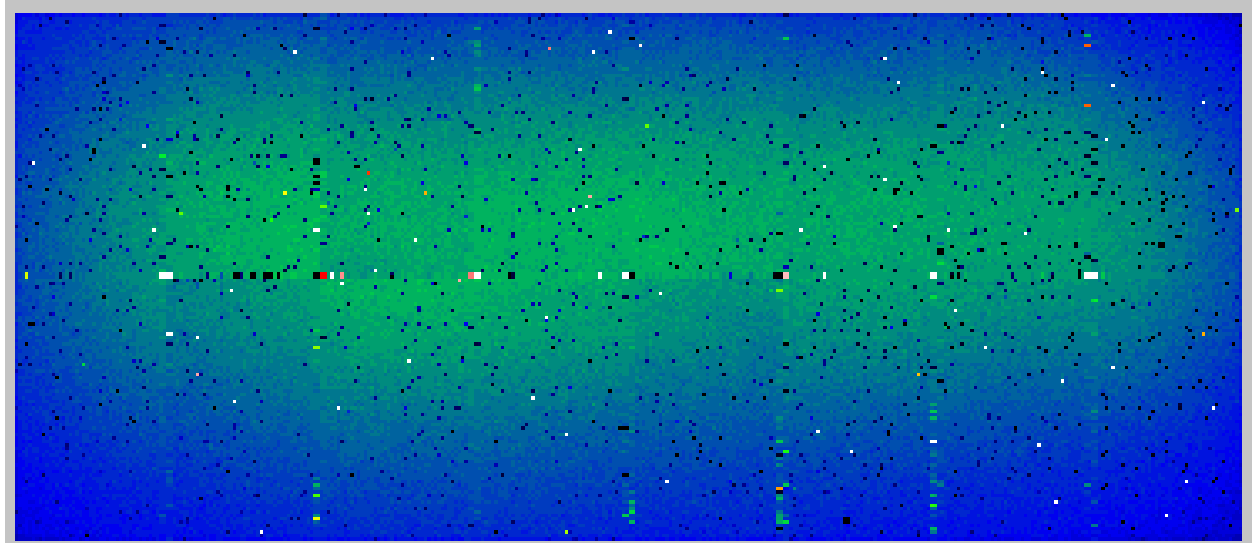
(Very sensitive to high resistivity bumps)

Quality

PILATUS I:

54912 pixels

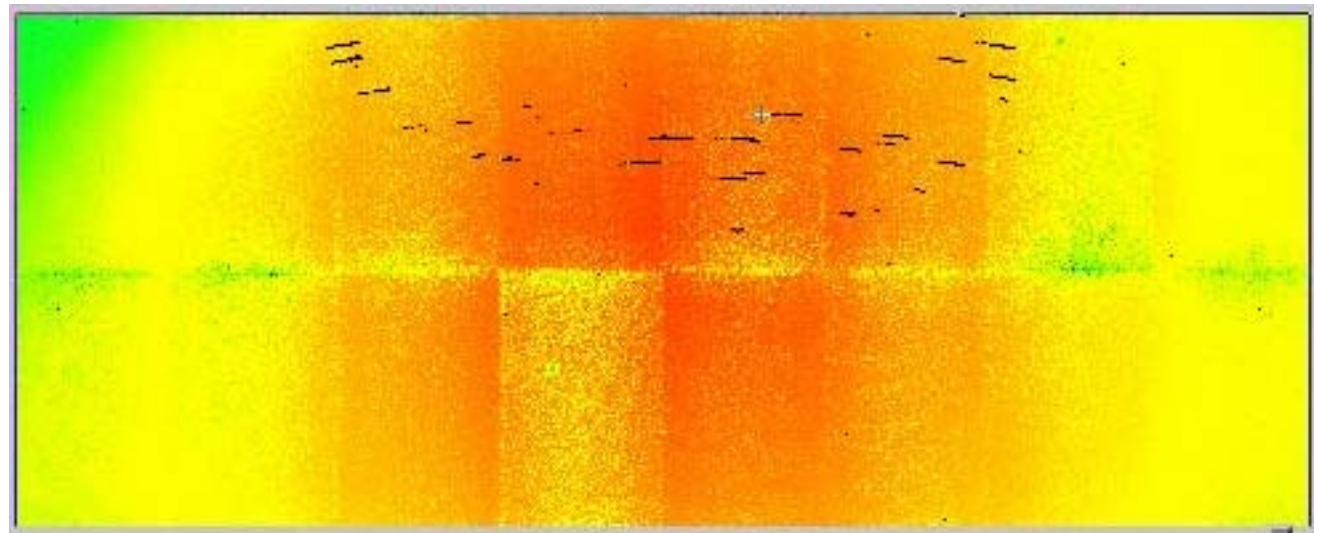
5% overall defects



PILATUS II:

93120 pixels

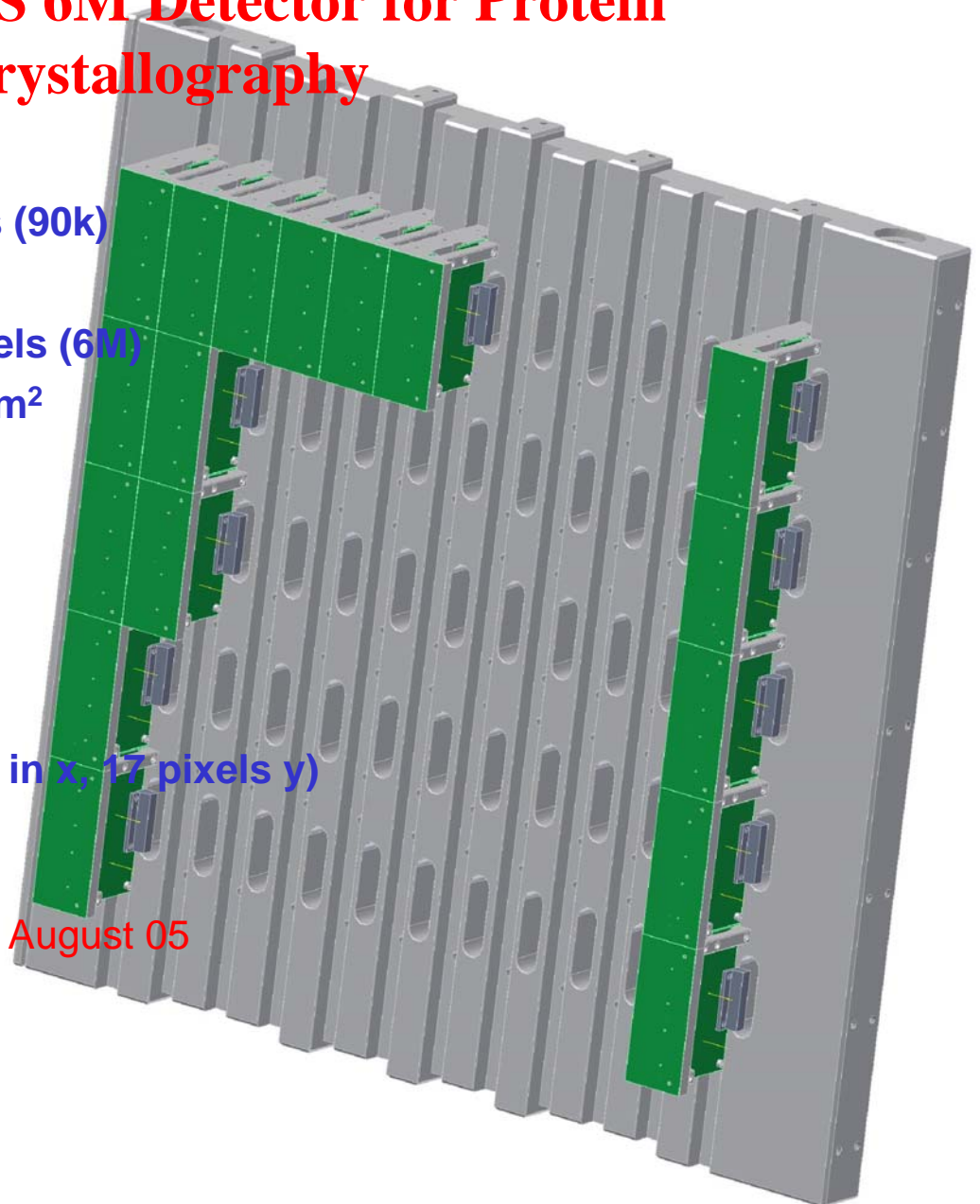
0.27% overall defects
(mainly sensor defects)



The PILATUS 6M Detector for Protein Crystallography

No of Modules	60
Module size	487 x 195 pixels (90k)
Detector Size	431 x 448 mm ²
No of Pixels	2527 x 2463 pixels (6M)
Spatial resolution	0.172 x 0.172 mm ²
Dynamic range:	20bits
Readout time	~2ms
Frame rate	5-10 Hz
Rate	1 MHz/pixel
Spatial distortion	Flat geometry
Dead area	~8.4 % (7 pixels in x, 17 pixels y)

Status: Module fabrication starts in August 05



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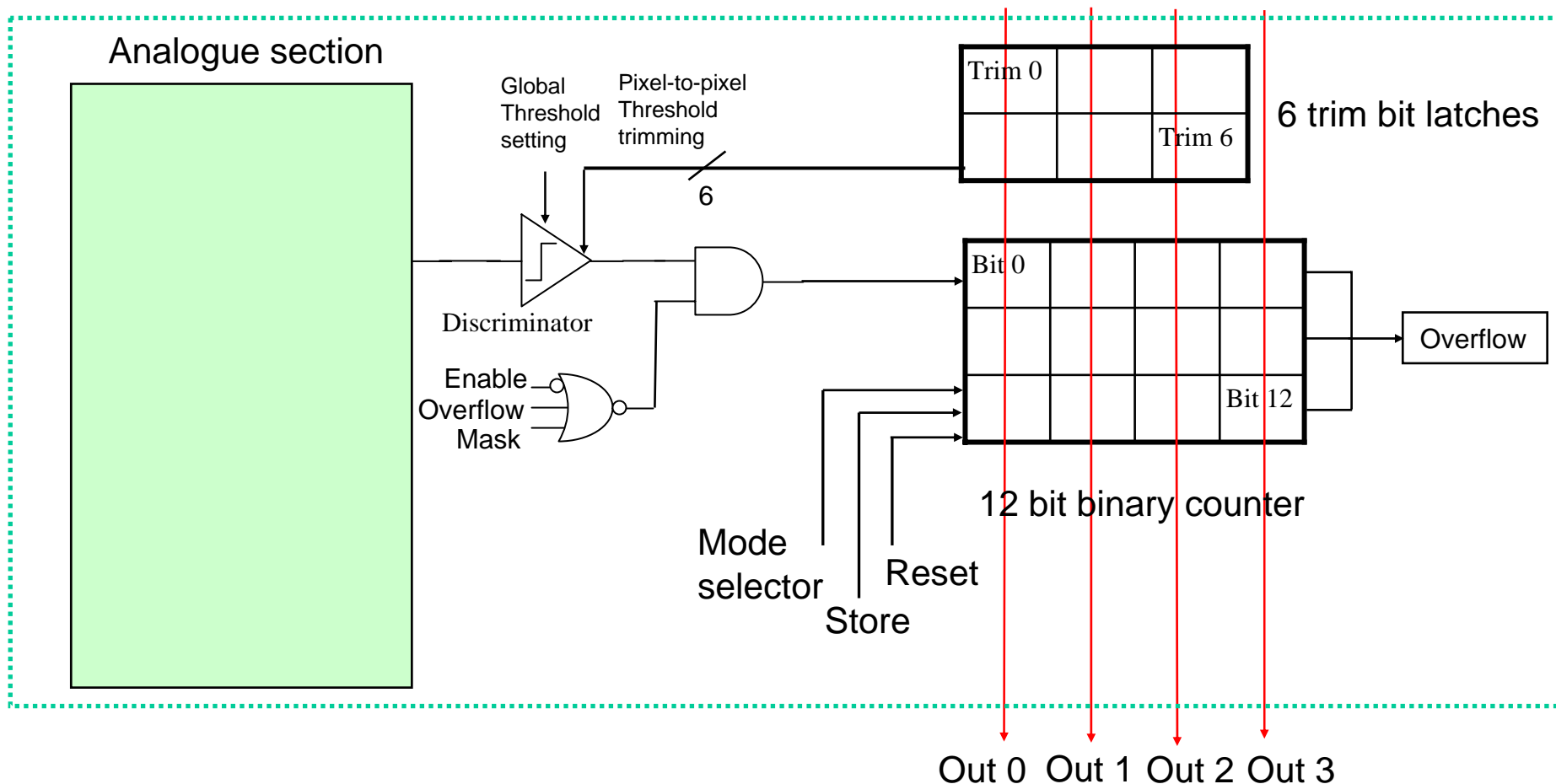
PILATUS XFS: (eXtrem Framing System)

(R. Horisberger, R. Dinapoli and Ch. Broennimann)

	Pilatus XFS	Pilatus II
Technological process	UMC 0.25 μm process	The same
Radiation tolerance	Radiation hard design ($>4\text{Mrad}$)	The same
Pixel array	$256 \times 256 = 65536$	$60 \times 97 = 5820$
Pixel size	$75 \times 75 \mu\text{m}^2$	$172 \times 172 \mu\text{m}^2$
Chip size	$19.2 \times 19.2 \text{ mm}^2$	$17.54 \times 10.45 \text{ mm}^2$
Counter	12 bits, binary, configurable (4,8,12 bit mode)	20 bits, pseudo-random, not configurable
Readout	Continuous	Separated from exposure
Local count rate	$> 10^6$ /pixel/s	$> 10^6$ /pixel/s
Overall count rate	$> 3 \times 10^8$ /mm ² /s	$> 5 \times 10^7$ /mm ² /s
Power consumption	$< 5 \text{ uW/pixel}$	10 uW/pixel
Frame rate full RO	$> 10 \text{ KHz}$	$< 300 \text{ Hz}$

Pilatus XFS, the pixel architecture

- The chip is a matrix of 256 x 256 pixels of **75 x 75 μm^2** each.
- It has a configurable count mode, 4, 8 and 12 bits. Moreover, it can be used in simultaneous read-write mode.
- This results in **12.5 KHz framing rate @ 8 bit, continuous readout mode.**



Pilatus XFS main features

•Count rate: 1MHz/pixel (3×10^8 x-rays/mm²/s)

Max. frame exposure time before overflow:

• T_{\max} @ 4 bit mode = 16 μ s

• T_{\max} @ 8 bit mode = 256 μ s

• T_{\max} @ 12 bit mode = 4 ms

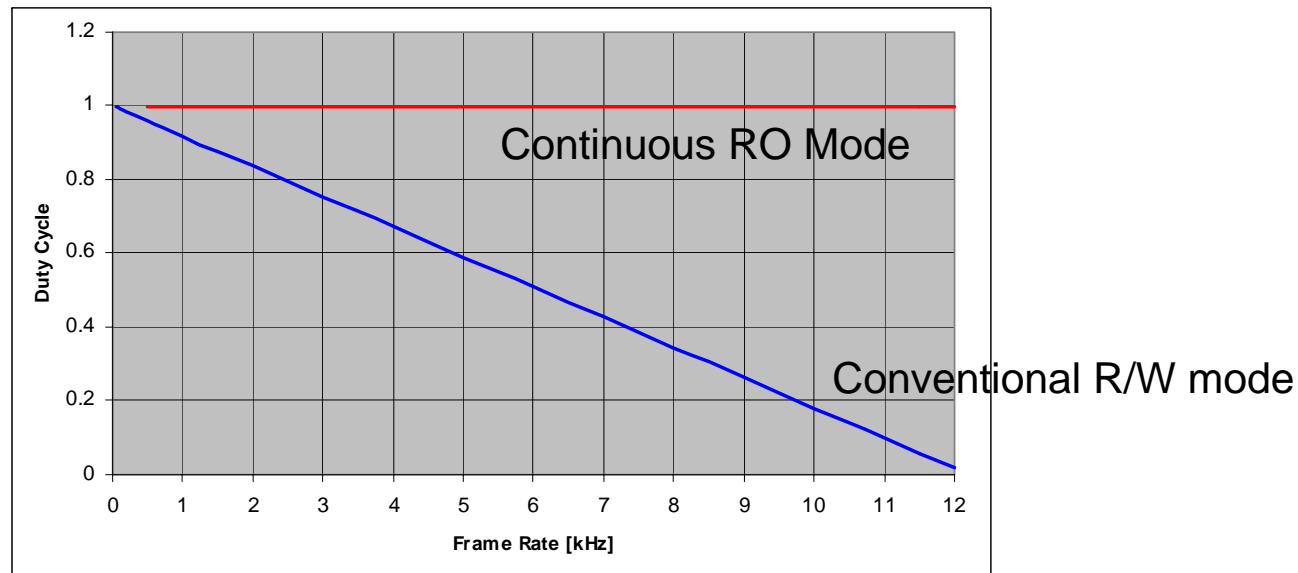
•200 MHz LVDS readout (PII:75 MHz)

• T_{ro} @ 4 bit mode = 40.96 μ s

• T_{ro} @ 8 bit mode = 81.92 μ s

• T_{ro} @ 12 bit mode = 122.9 μ s

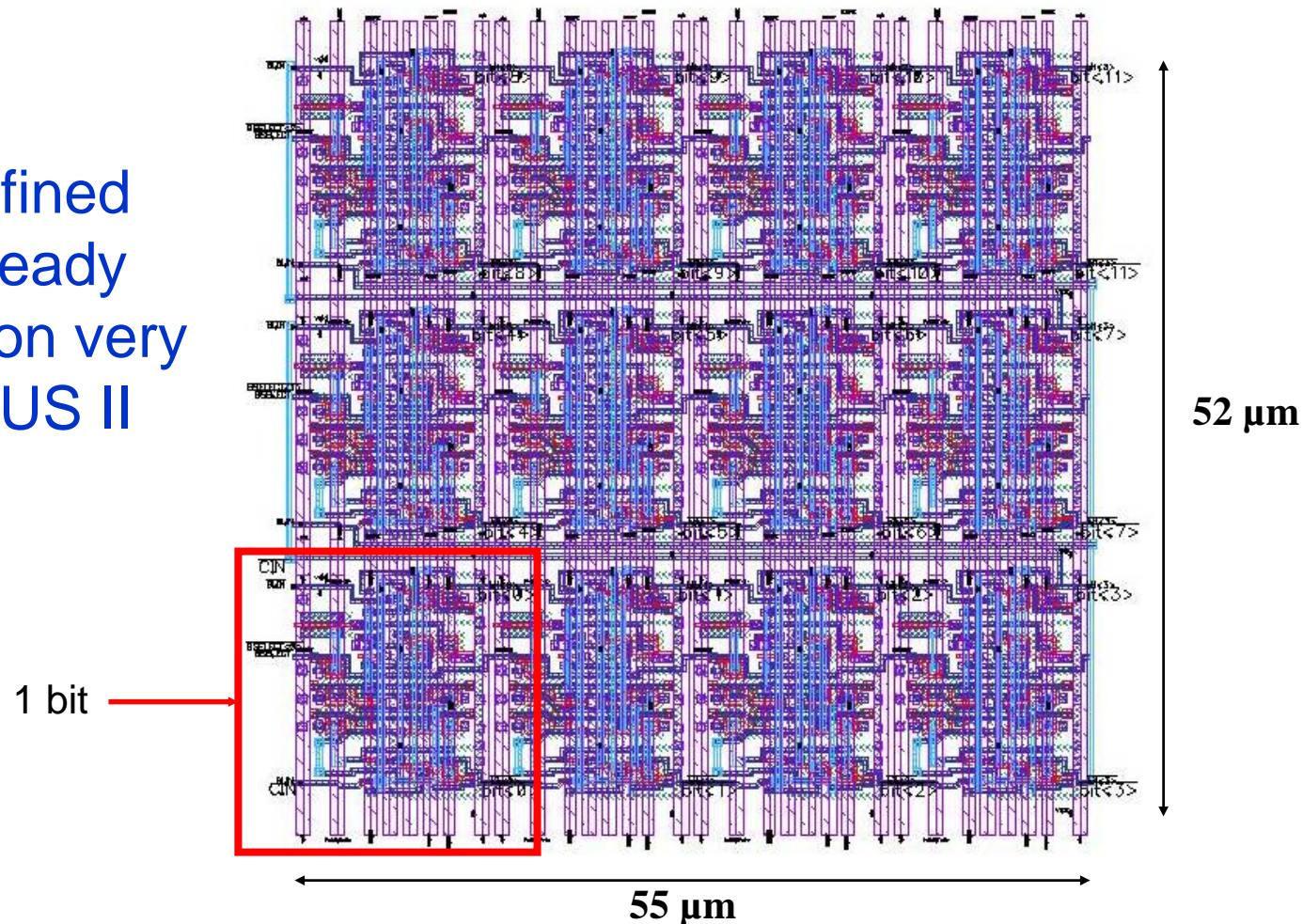
•In continuous readout mode, frame rate=1/readout time; **12.5 KHz @ 8 bit mode**



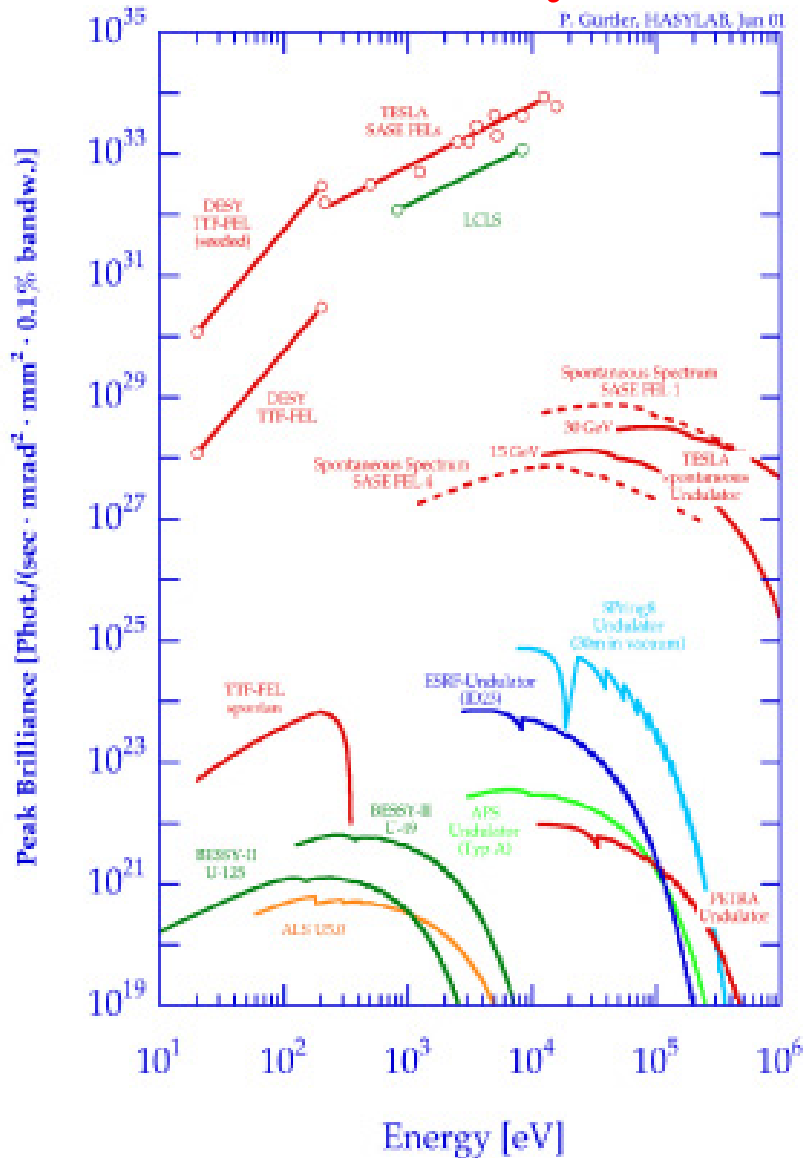
Pilatus XFS, status

Configurable 12 bit counter with latch

- Architecture defined
- 12 bit counter ready
- Analogue section very similar to PILATUS II



Future synchrotron sources



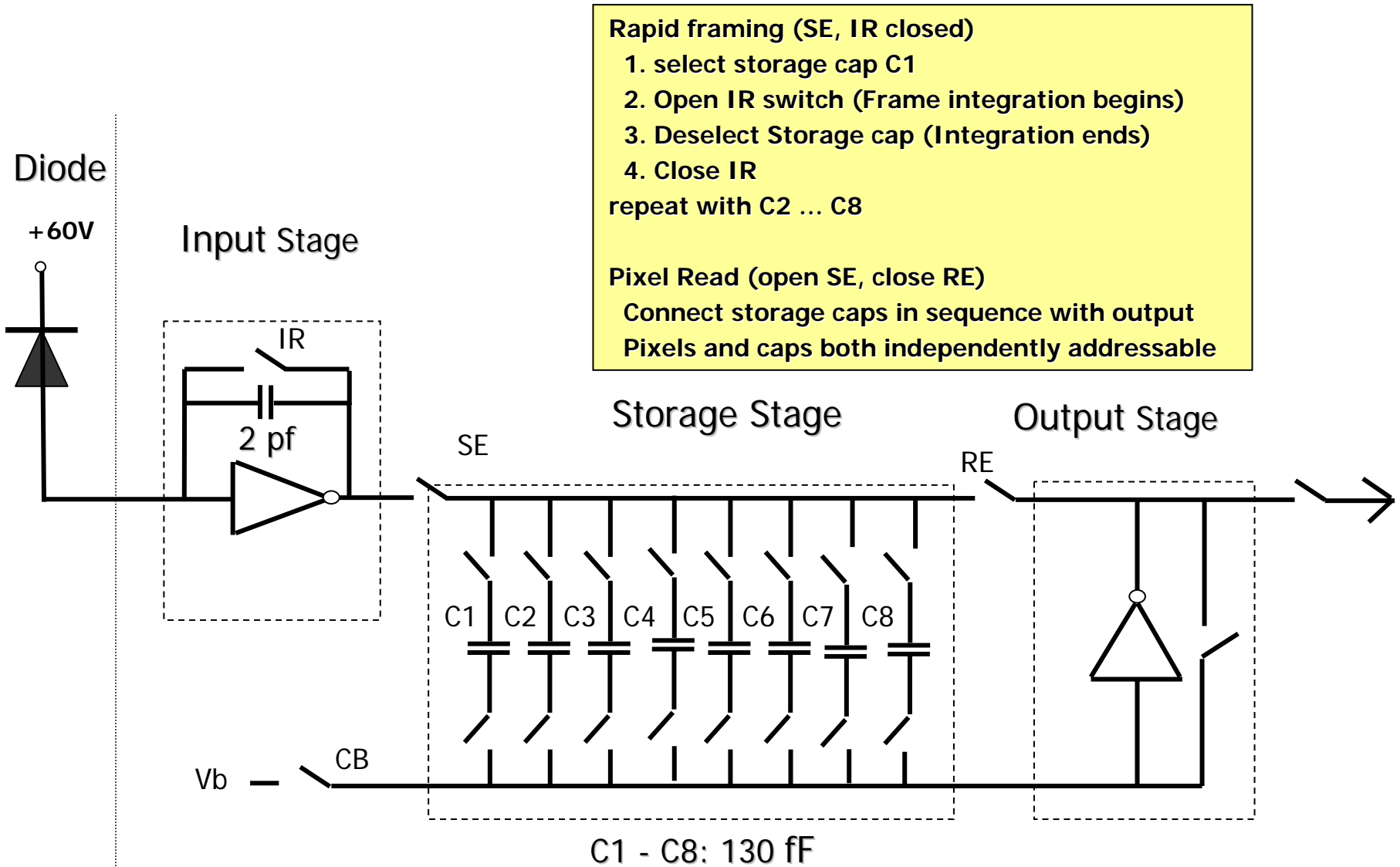
Peak intensities several order of magnitudes higher -> counting impossible

-> Integrating detectors

Cornell Analog PAD



CHASS & LASSP



Cornell 100x92 Analog PAD

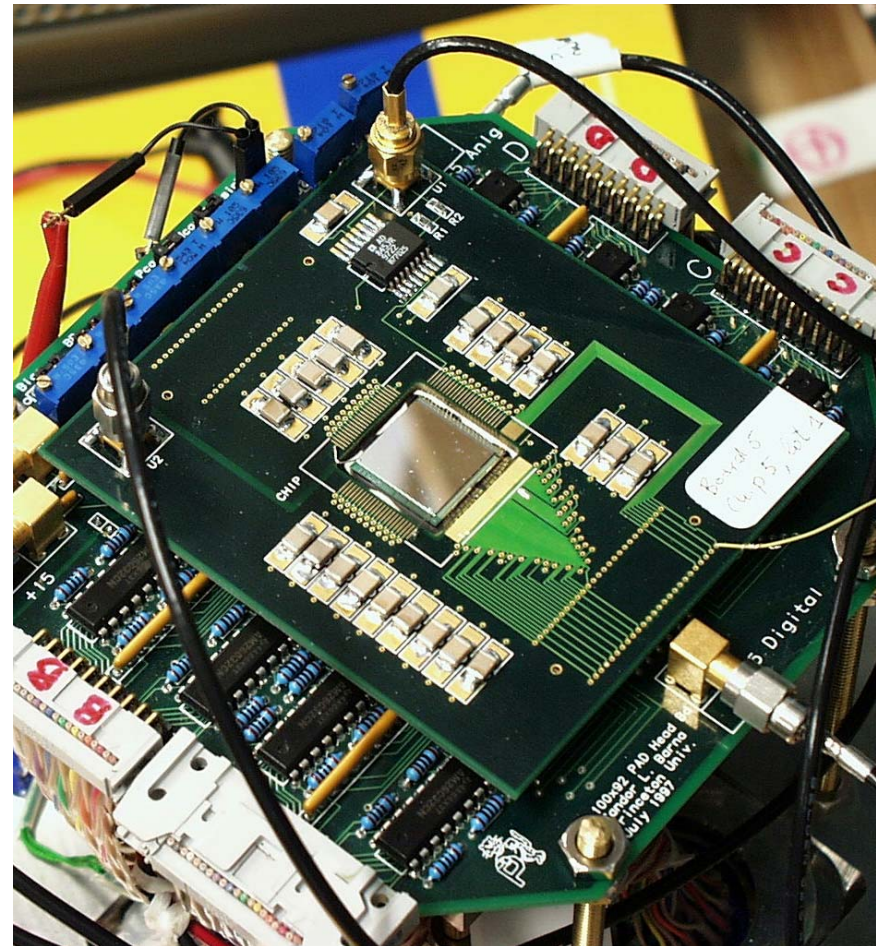


CHESS & LASSP

- 1.2 μm HP CMOS process (MOSIS)
(Linearized Capacitors)
- 15 x 13.8 mm² active area; 100x92 pixels
- 150 μm square pixel
- 300 μm thick, high resistivity Si diode wafer (SINTEF)
- 120 μm solder bump bond (GEC-Marconi)

100x92 PAD developers include:

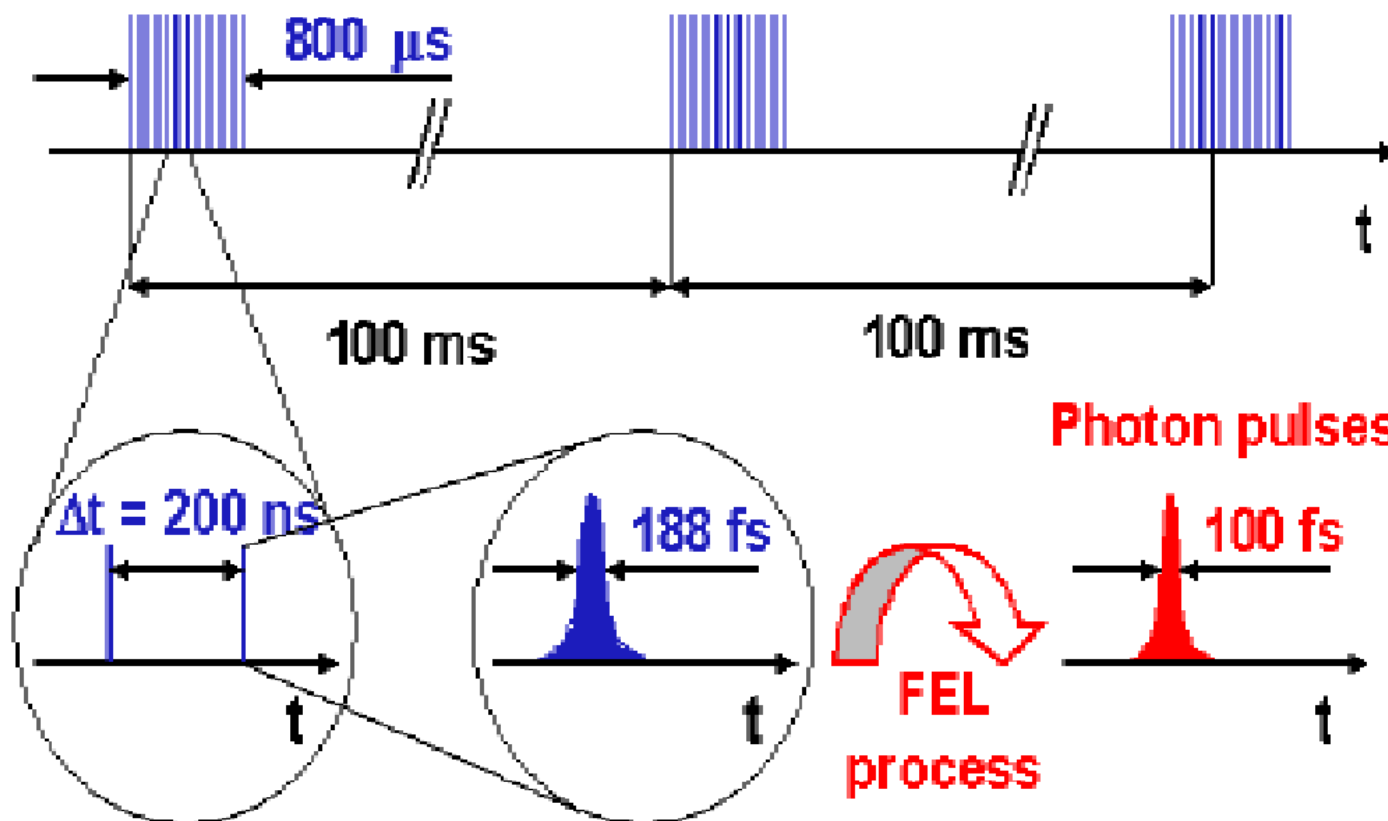
- Sandor Barna
- Eric Eikenberry
- Alper Ercan
- Sol Gruner
- Matt Renzi
- Giuseppe Rossi
- Mark Tate
- Bob Wixted



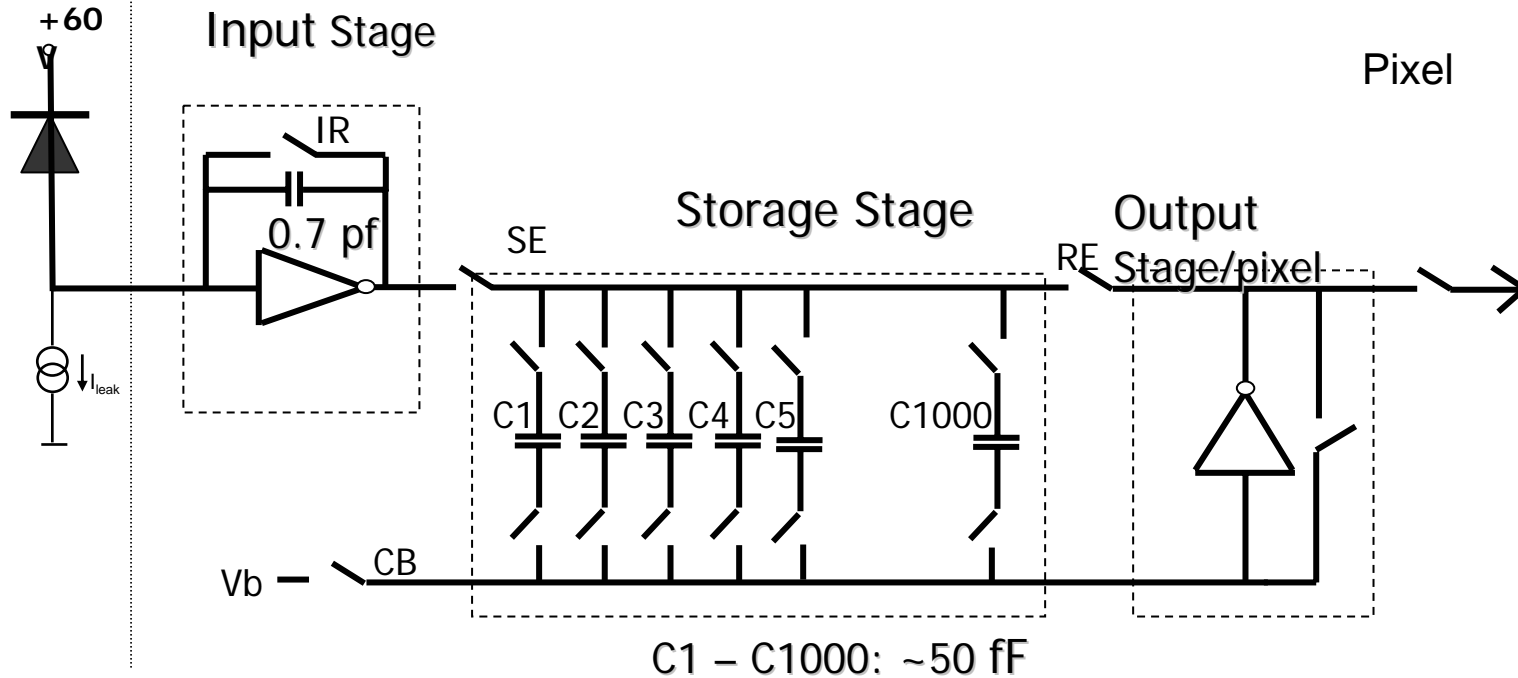
G. Rossi, *et al*, J Synchrotron Rad. (1999). **6**, 1095-1105.

Tesla FEL

Electron bunch trains
(with up to 4000 bunches à 1 nC)



Pixel Chip for Tesla FEL

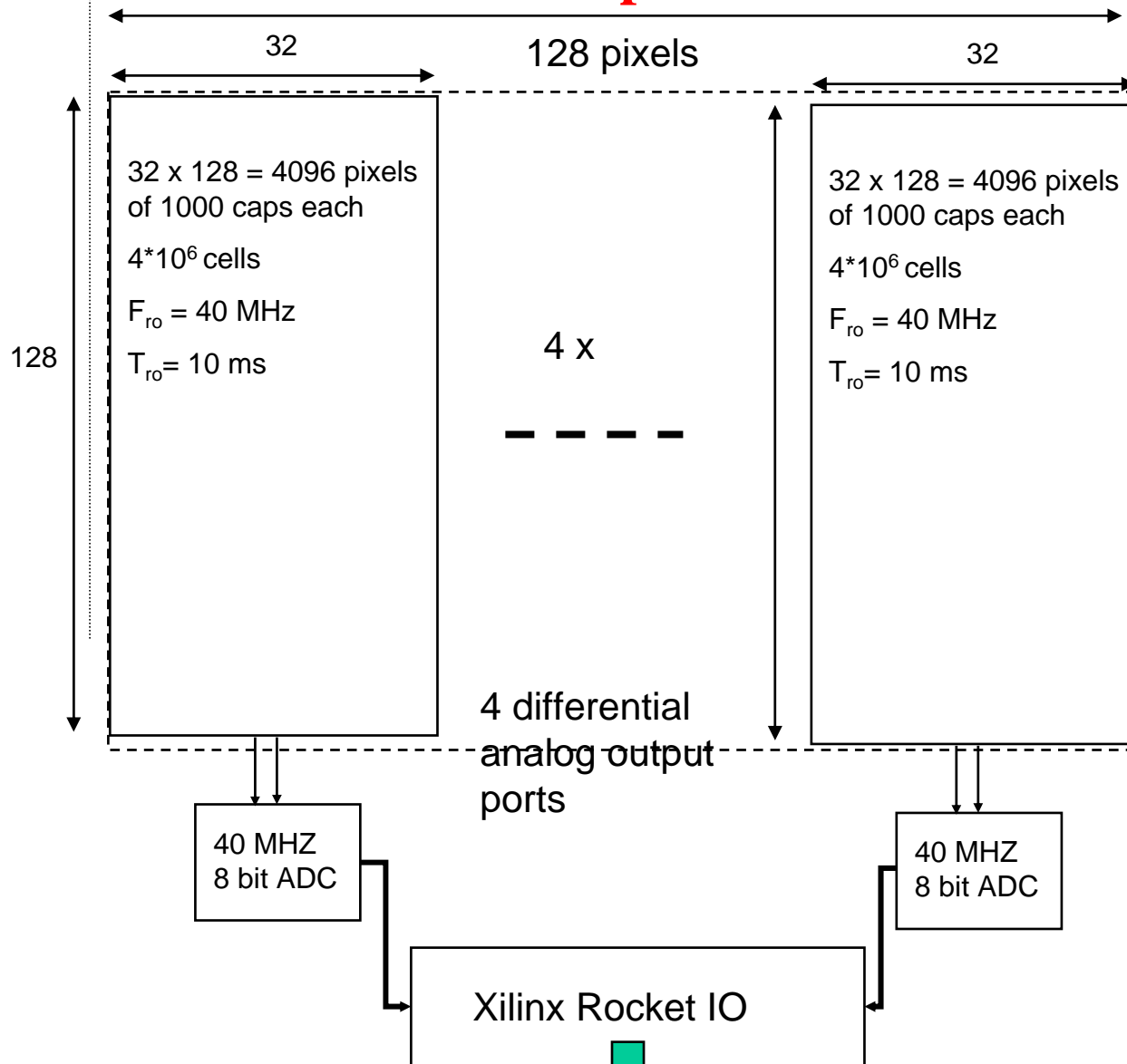


Rough dimensions:

$\sim 20 \text{ } \mu\text{m}^2$ / cap cell \rightarrow 1000 caps (frames) $\sim 140 \times 140 \text{ } \mu\text{m}^2$

\rightarrow Pixel size $\sim 160 \times 160 \text{ } \mu\text{m}^2$

Pixel Chip for Tesla FEL



Detectors for Current and Future Synchrotron Light Sources

1. Introduction
2. Existing Detector Systems
 - Rapid
 - Mythen
 - Pilatus
3. Future Detector Systems
 - Pilatus XFS
 - APAD
 - Analog Hybrid Pixels for FEL Apps
4. **Summary and Conclusions**

Time scales for detector developments

	91	92	93	94	95	96	97	98	99	00	01	02	03	04	05	06	07	08	09	
Rapid	MWPC Developements					First Beam Tests			Rapid 1				Rapid 2 @SPRING 8							
Frelon	CCDs Since 1980													Commercially available						
Pixels @CERN		Omega 3 Chip WA97, 300kPix			Delphi Vertex 613 kPix							Alice Chip								
Medipix						Medipix 1 64 x 64, .17 ²				Medipix 2 (IBM) 256 x 256, .05 ²			Medipix 2 Rad Hard							
CMS Pixel @PSI						PSI 30 22 x 30					PSI 46 (DM) 54 x 53		PSI 49 (IBM) 54 x 53							
Pilatus										P I (DM) 44 x 78, 0.21 ²		P 1M 10 ⁶ Pix		P II Chip PSI50 60 x 97, 0.17 ²						
Mythen										M I (DM) 128, 0.05		M I 12 Mod 16 k Strips		M V2 (IBM)						
APAD							APAD 100 x 92					APAD Push Pull								
Detectors for FEL																				→

Summary

Single photon counting pixel detectors are becoming more and more mature
-> much higher local and global count rates.

Next generation of single photon counting detectors are currently in the design phase (Medipix 3? and Pilatus XFS)
Higher frame rates resp. higher spatial resolution

Next generation of SR sources will require analog integrating pixel detectors

Developments take roughly 7 years

If we want to be ready, we have to start now

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